

Si Photonics for Advanced Communications



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Silicon Photonics Research Directions

Integrated Optical Technology for Communication and Signal Processing

■ High Performance Computing

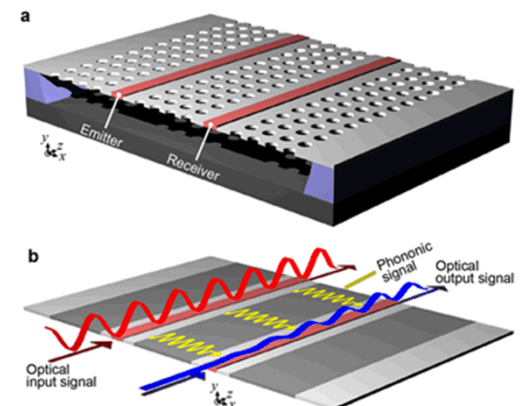
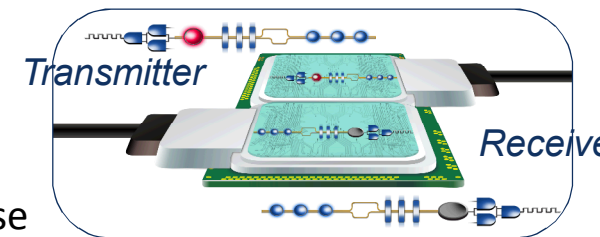
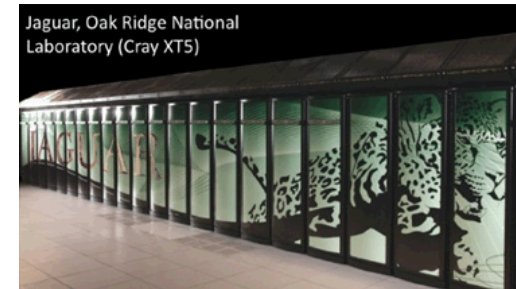
- Optical Interconnect
- XGC Grand Challenge FY12-14 (wavelength stabilization, heterogeneous integration, low-power comm. link modeling/design)

■ RF Photonics

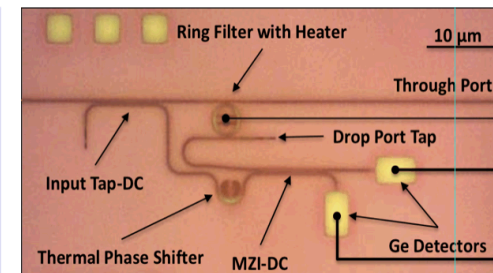
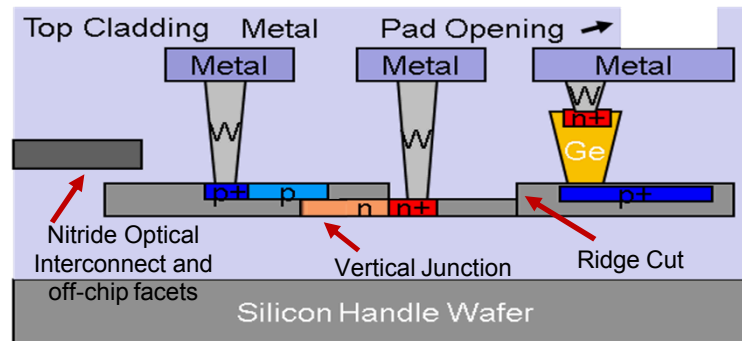
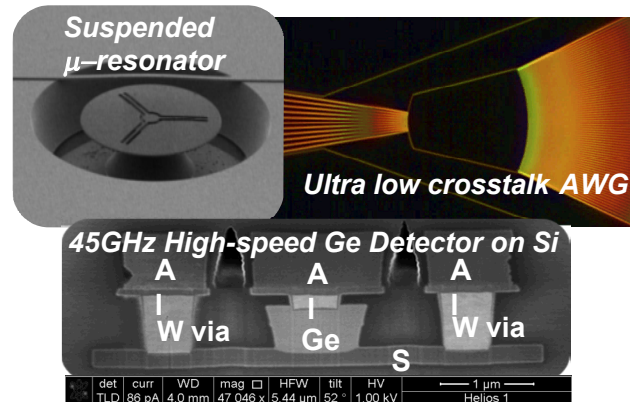
- 110 Channel Cueing Receiver FY12-15 (low-loss waveguide, phase correction)
- DARPA MESO FY12-15 (photon-phonon coupling, RF filters)
- High speed optical modulator FY15-16 (nonlinear material)

■ Quantum Photonics

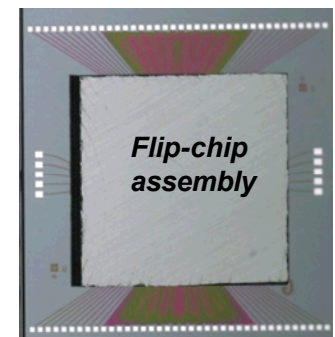
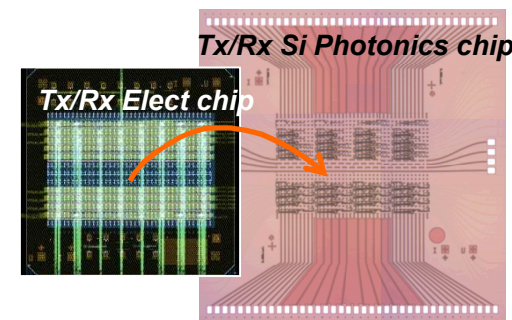
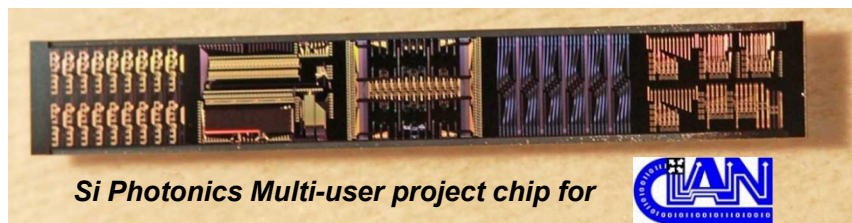
- SECANT Grand Challenge FY14-16 (QKD transceivers)
- Continuous and Discrete Variable Quantum Key Distribution.
- Chip-scale Quantum Coherent Feedback and Control.



Sandia Si Photonics Integrated Circuits



Filter with wavelength stabilization



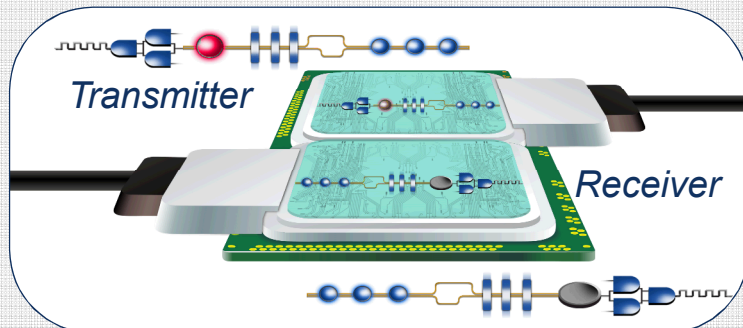
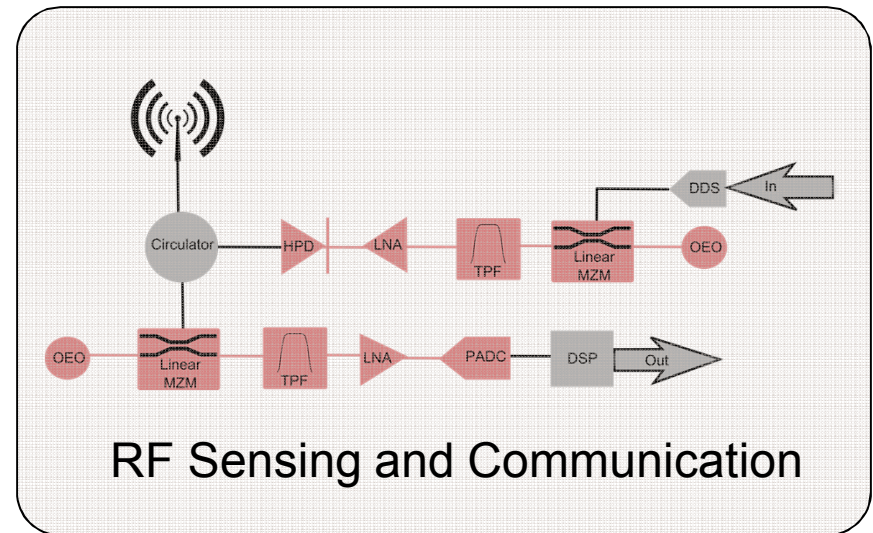
Silicon-based Optical Communication Devices

- **Active Components:** Linear and digital Mach-Zehnder modulators, ring and disk ultra-low energy modulators with/without integral micro-heaters for resonant wavelength stabilization, high-freq. and high power integrated germanium detectors, integration with rad-hard CMOS, 2 x 2 wavelength selective switches and broad-band switches, and tunable filters
- **Passive Components:** wavelength division multiplexers using resonant filters and arrayed grating routers, surface normal and in-plane polarization beam splitters, polarization rotators, polarization mode filters, directional couplers and splitters, integral SiN second photonics routing layer, Sagnac interferometers, AWG RF channelizers
- **Demonstrated Circuits:** transmitters, receivers, on-chip links, resonant wavelength stabilization circuits for both modulators and filters, optical active beam steering, optical logic (matrix multiply), low noise oscillators, optical network add-drop node (CIAN), optical channel monitor (spectrum analyzer) (CIAN)

Photonics Enabled System Applications

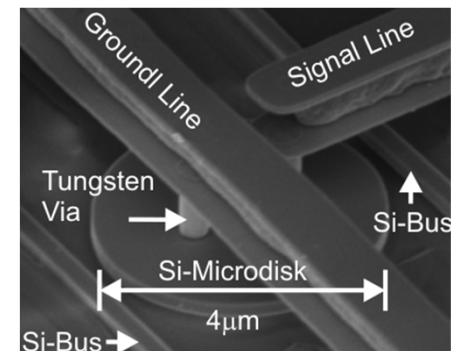
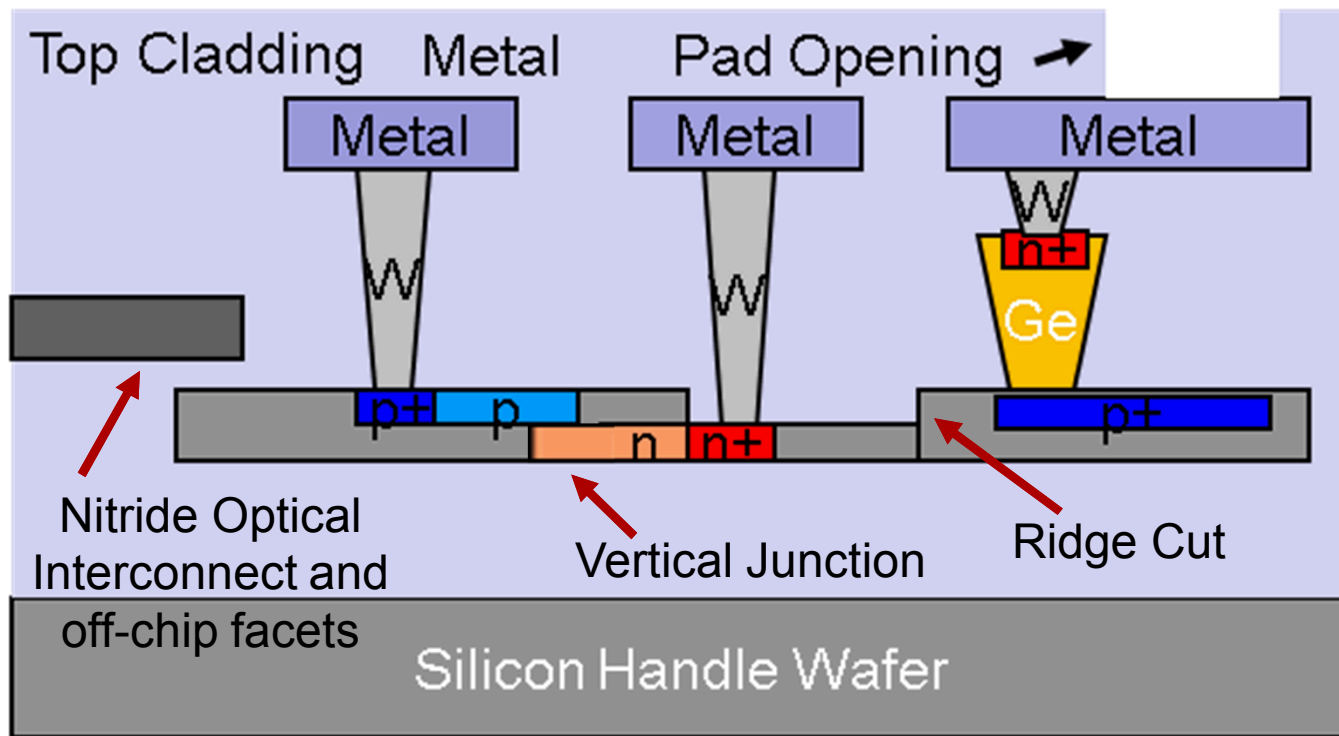


High Performance Computing

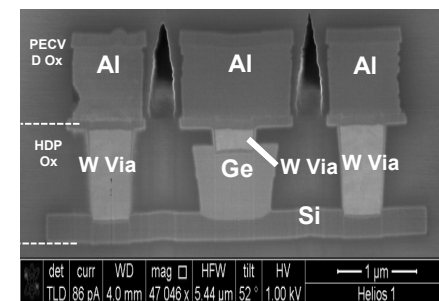


Secure Quantum Communication

SNL Silicon Photonics Process



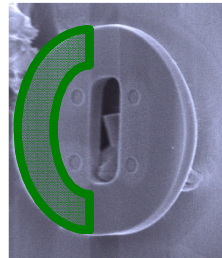
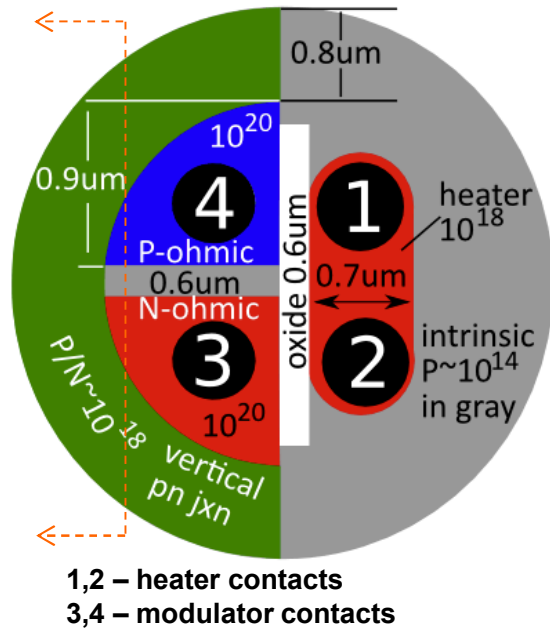
Optical modulator
12.5GHz, 3fJ/bit



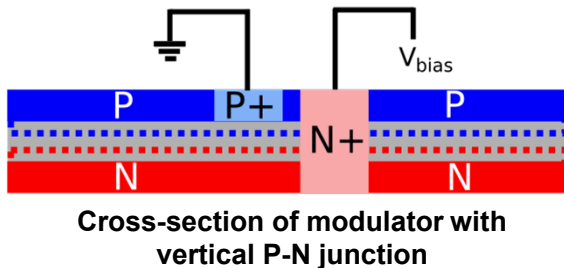
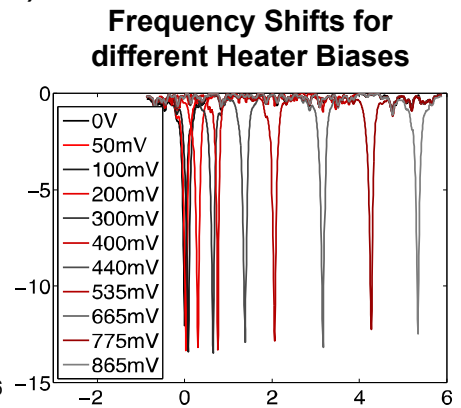
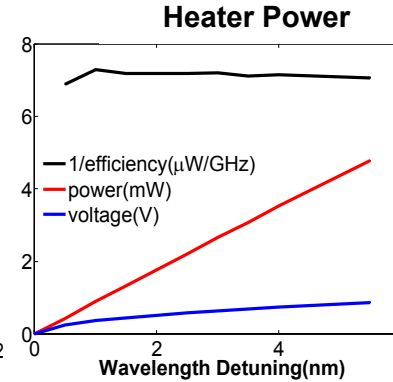
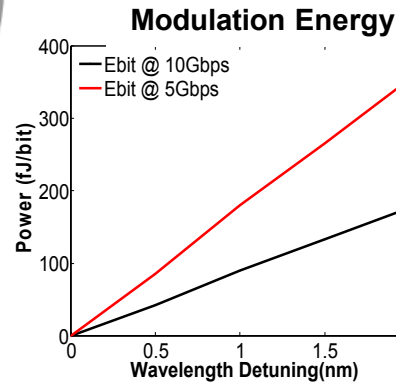
Ge photo detector with
45GHz BW, 3nA dark current

- CMOS compatible
- Passive and active photonics devices
 - Silicon and silicon nitride waveguides, couplers, splitters, gratings, filters, modulators, Germanium detectors, switches, etc.

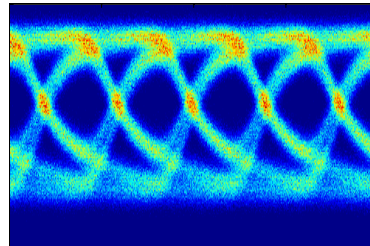
10Gbps Resonant Heater Modulator Sandia National Laboratories



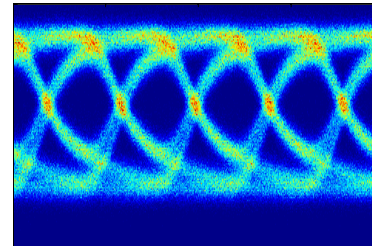
- FSR covers entire C-band
- Low footprint of $\sim 14\mu\text{m}^2$, CMOS-compatible
- Differential signaling compatibility
- Lowest intrinsic tuning energy
 $7\mu\text{W}/\text{GHz}$ ($0.7\text{fJ}/\text{bit-GHz}$)



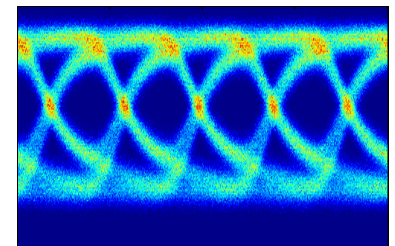
$\Delta\lambda = 0\text{nm}$ $\Delta T = 0\text{C}$ $\phi = 0\text{mV}$ $i = 0\text{A}$



$\Delta\lambda = 2\text{nm}$ $\Delta T = 25\text{C}$ $\phi = 535\text{mV}$ $i = 3.4\text{mA}$



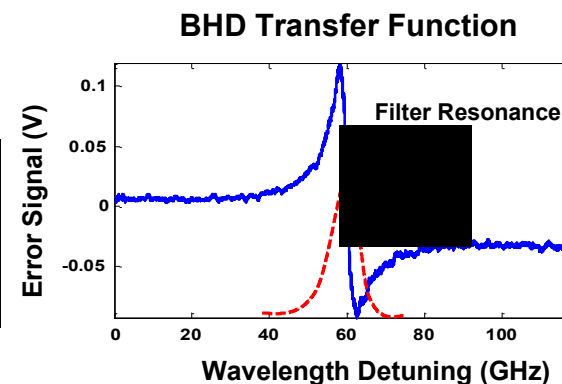
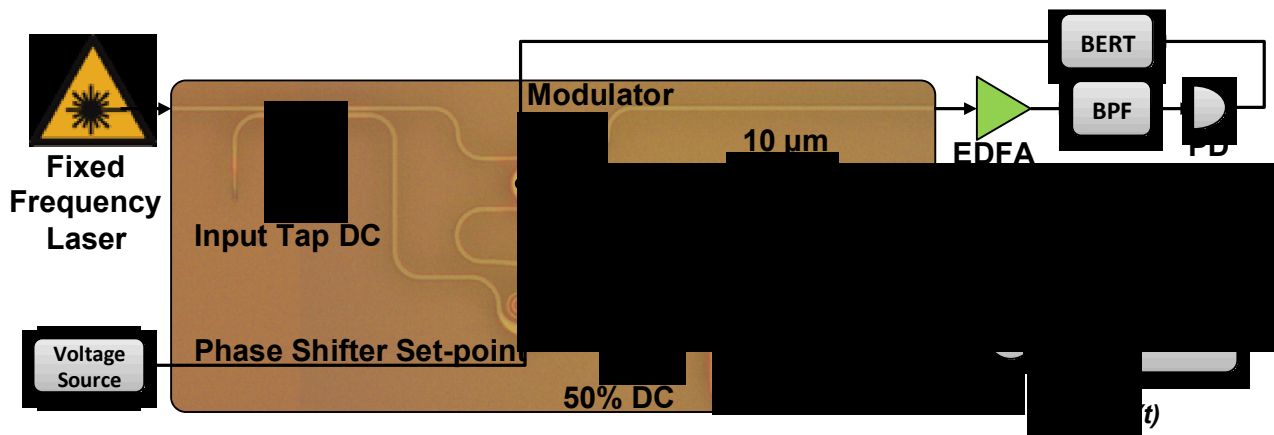
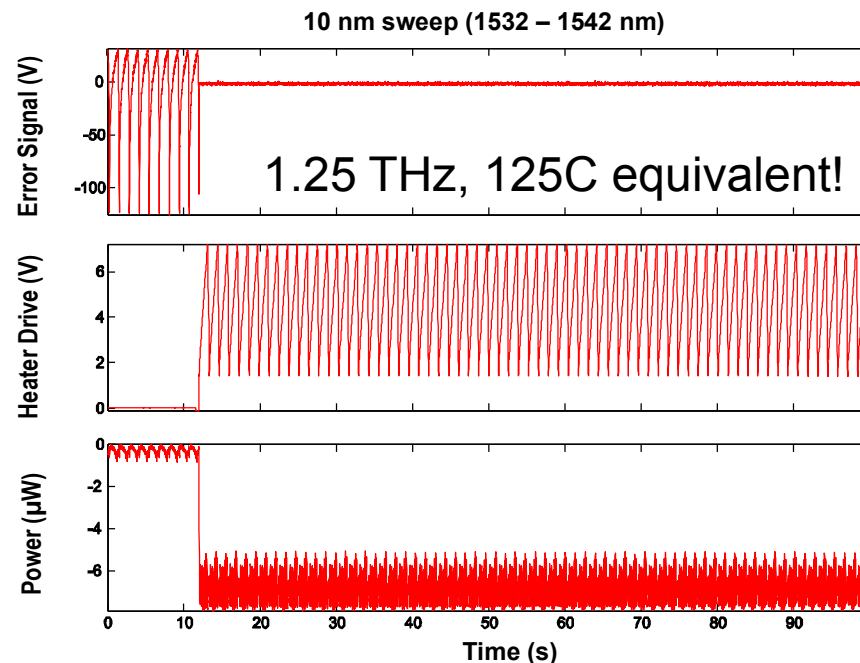
$\Delta\lambda = 5\text{nm}$ $\Delta T = 64\text{C}$ $\phi = 865\text{mV}$ $i = 5.24\text{mA}$



Similar eye diagrams achieved at different tuning temperatures

Stabilization of Modulators

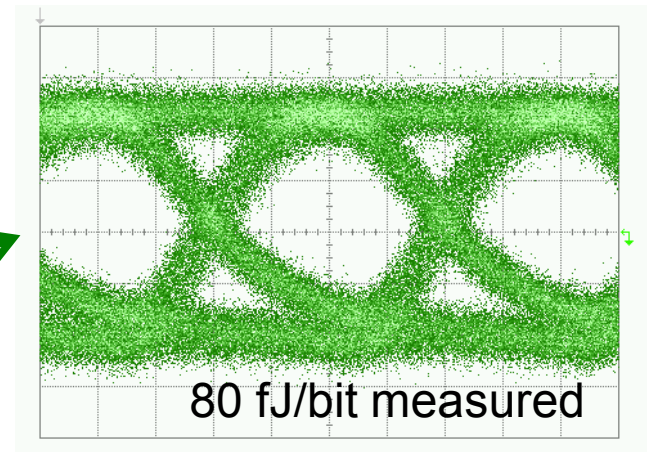
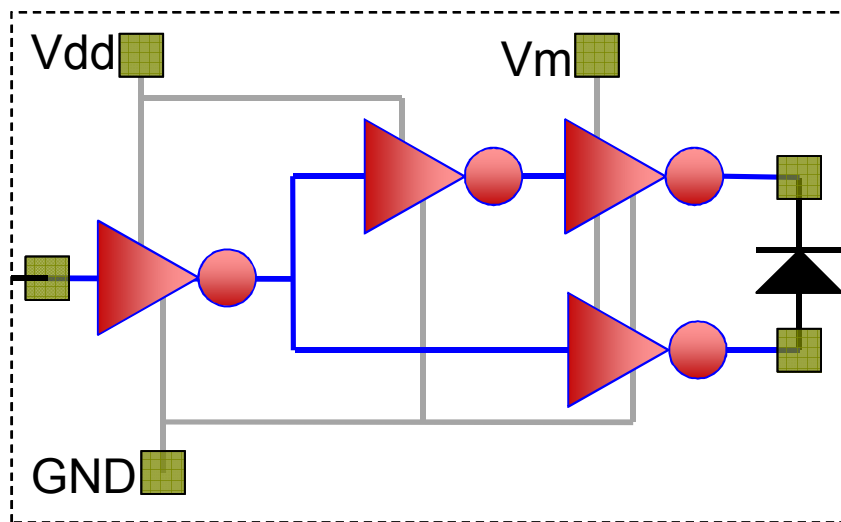
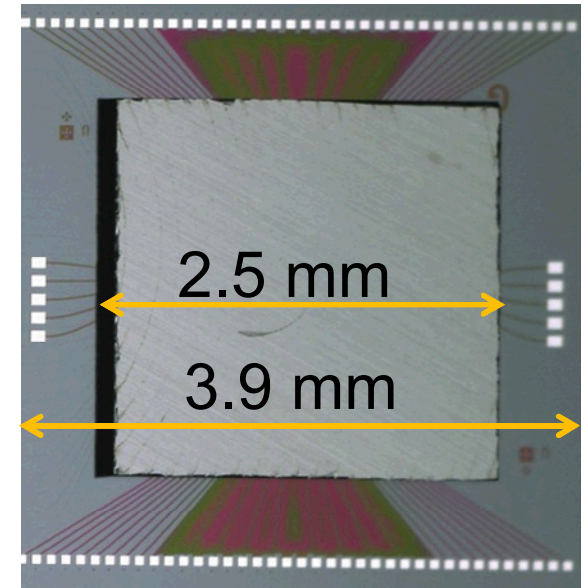
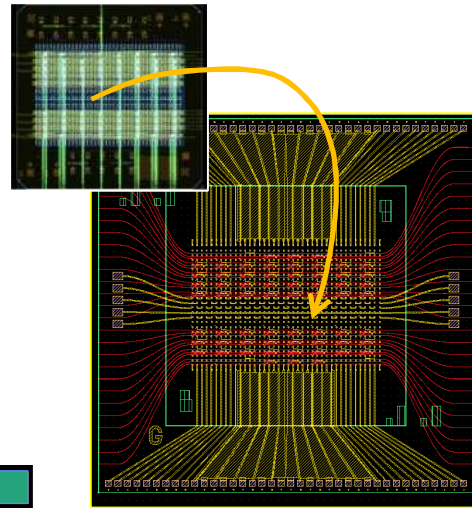
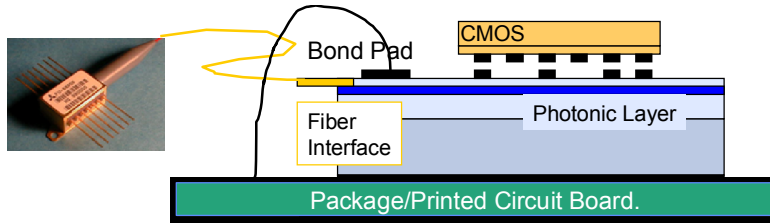
- **Lock to zero:** No calibration or reference level needed for locking
- **Amplitude insensitive:** Locking point not influenced by optical intensity
- **Precision locking:** Resonator is not disturbed
- **Minimum circuit complexity:** Power and area consumption of control electronics is minimized



Electronics – Photonics Integration

Heterogeneous Integration

- Independent optimization of electronics & photonics
- Challenge: Need high yields and small bond size

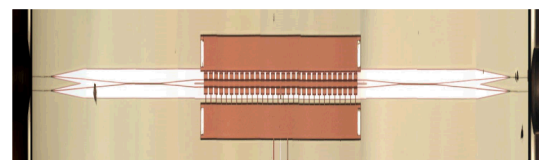
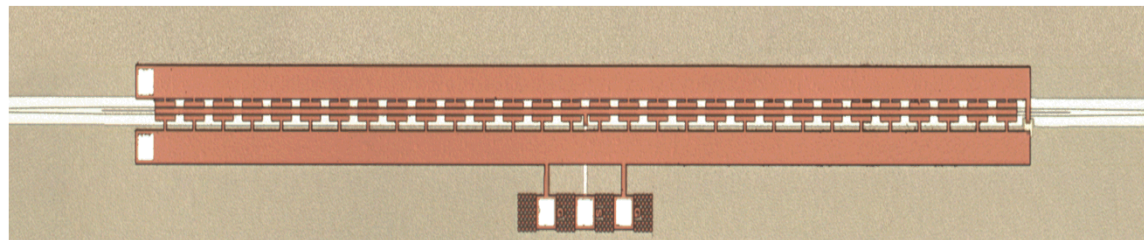


Modulated optical output at 5 Gbps

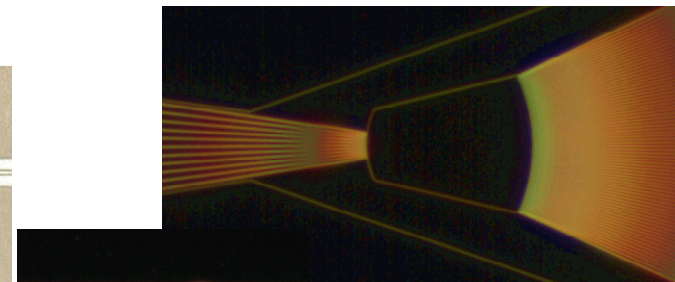
SNL RF Si Photonics Technologies

Silicon Photonics

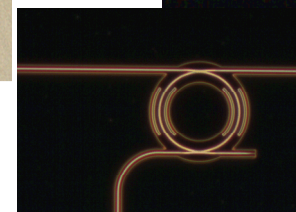
Optical modulation and spectrum analysis up to 100GHz



*Mach-Zehnder Modulator with
Traveling-Wave Electrodes
20GHz, $V_{\pi} \times L = 0.8\text{Vcm}$*



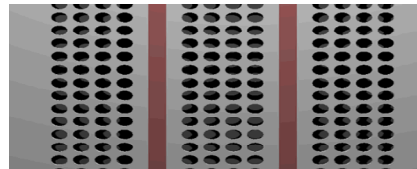
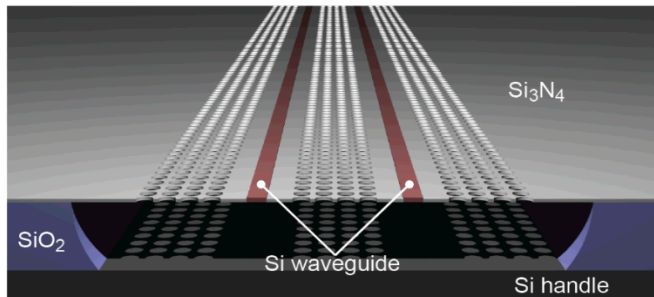
*Array Waveguide
Grating Coupler*



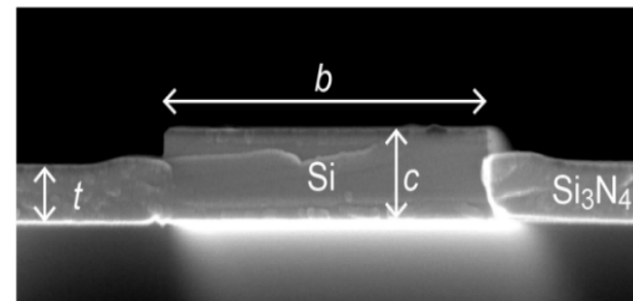
*Micro-ring Tunable
Filter (MHz – GHz)*

Silicon / SiN Nano-Optomechanics

Photon-phonon transduction for signal processing with up to 20GHz BW

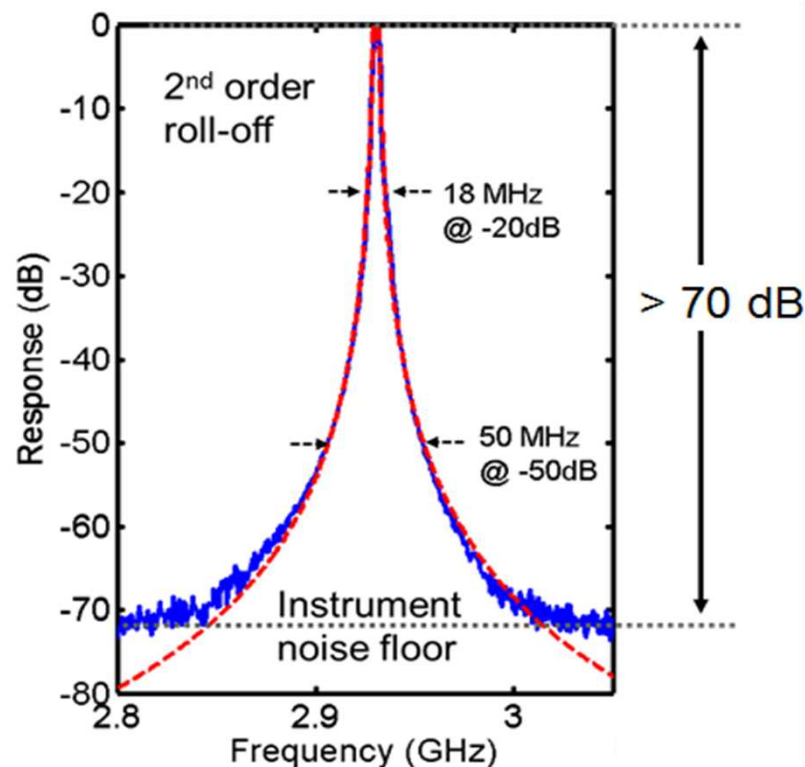
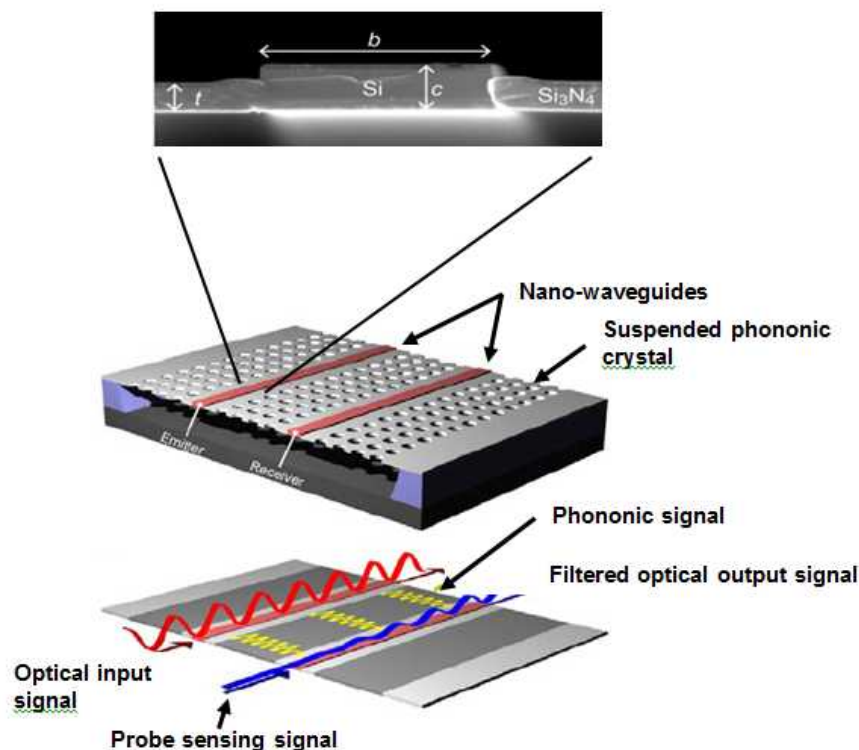


*Suspended Si waveguides
with phononic crystals*



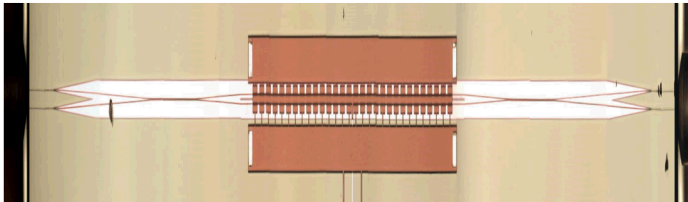
- New paradigm for RF signal processing (ex. filtering) in optical domain to reduce size, weight, and power, and improve performance

Photonic-Phononic RF Filter

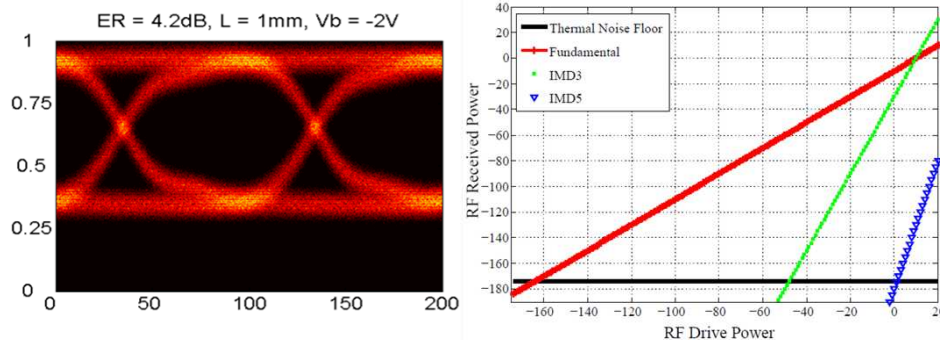


- Center frequency may be tunable between 1-20GHz;
- Q and filter shape may also be tunable
- Parallel / serial configurations to build filter banks/spectrum analyzer with significant size, weight, power, and performance benefits

SNL RF Si Photonics Technologies

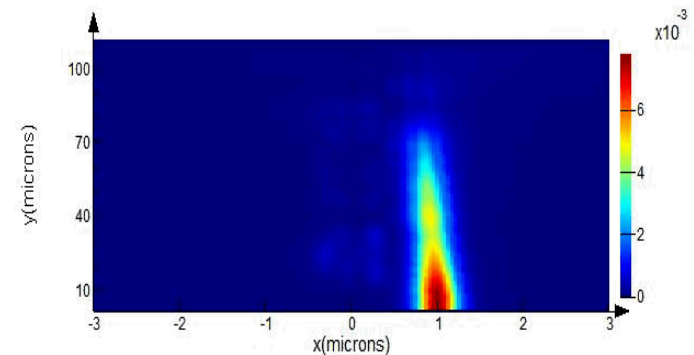
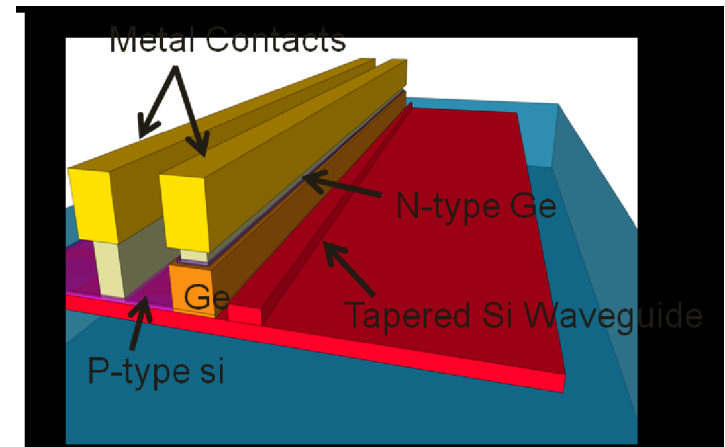


*Mach-Zehnder Modulator with
Traveling-Wave Electrodes*



■ High-bandwidth linear modulator

- 23GHz, $V_{pi} \times L = 0.8\text{Vcm}$, 108 dB/Hz^{2/3}
- Analog to Digital Conversion, RF Filtering and Antenna Remoting
- Side-band modulation in chip-scaled Continuous-Variable QKD
- Next step – CMOS integration to control drive voltages and minimize signal attenuation

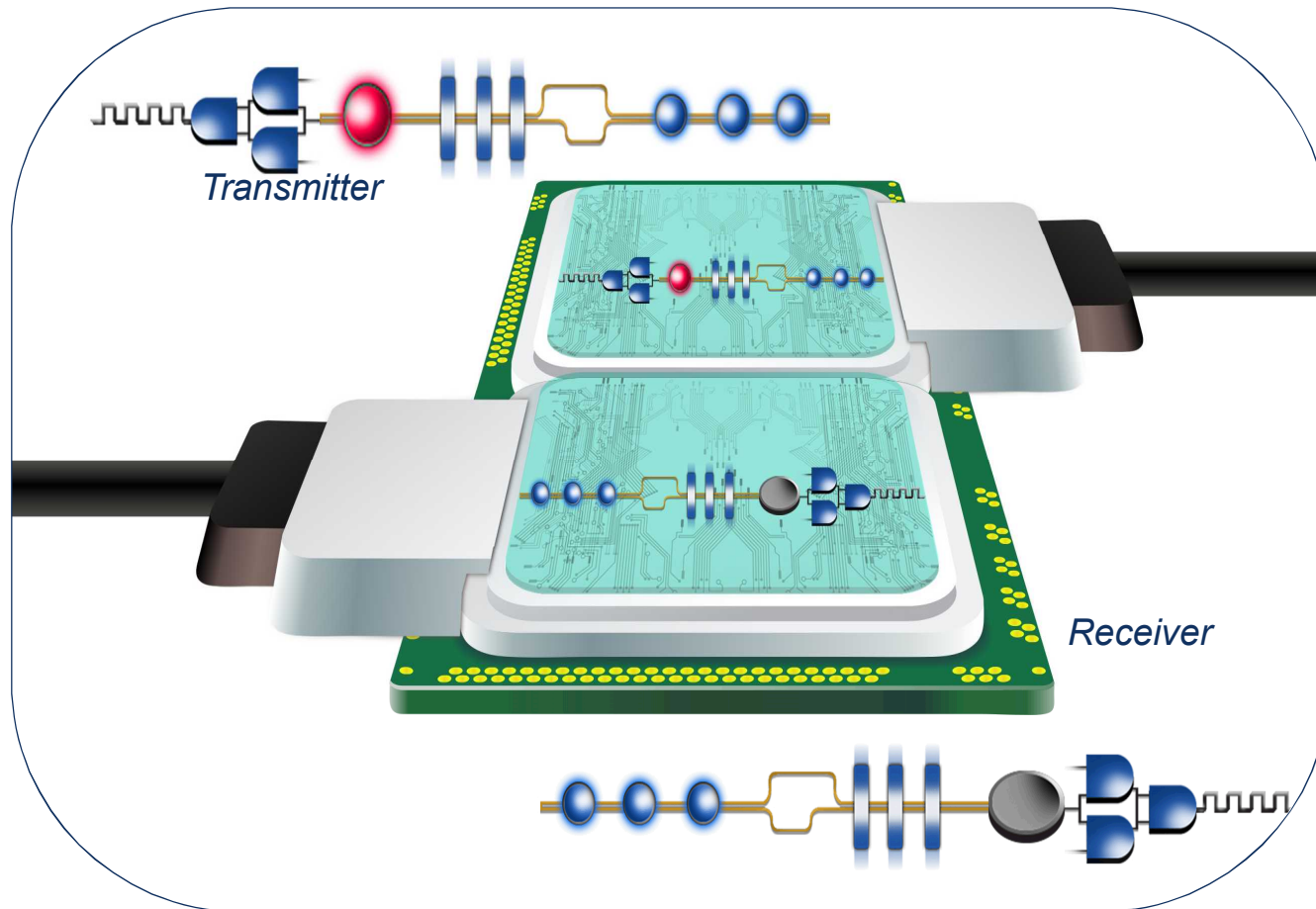


■ High-power optical detector

- Waveguide coupled
- 20mW power-handling
- 1500-1600nm operating wavelength

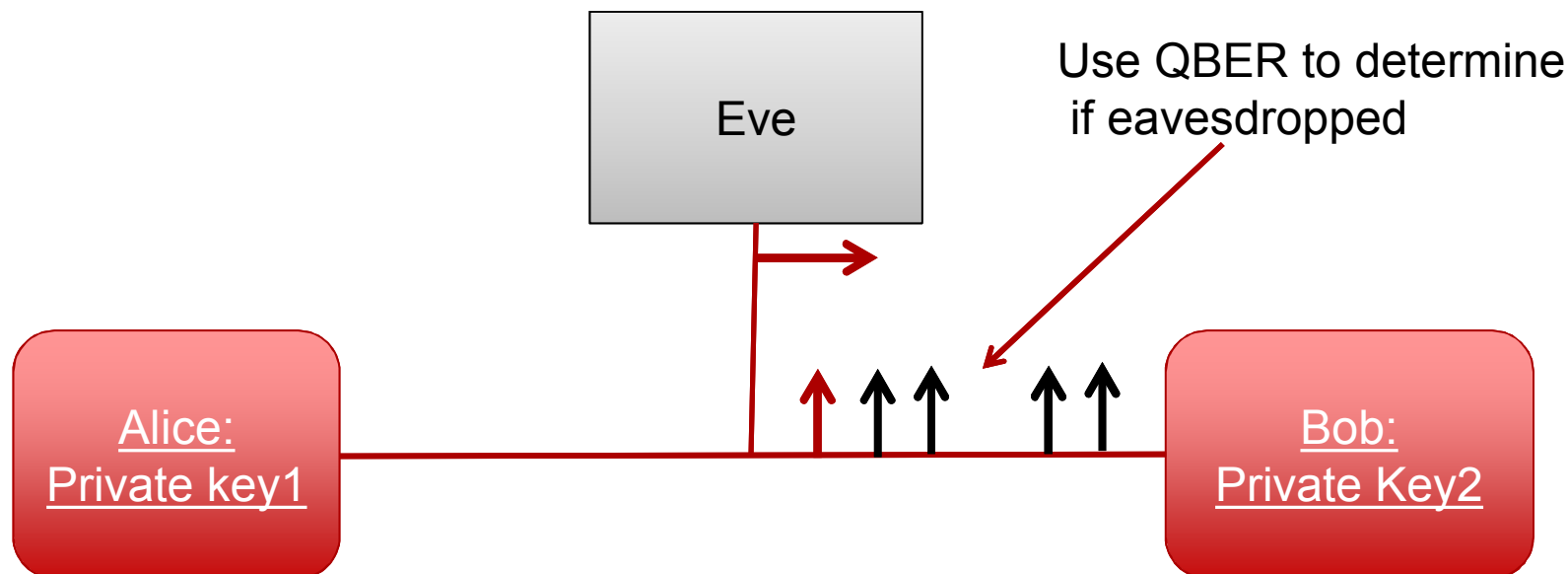
Chip-scale Quantum Tx/Rx for QKD

Develop new building blocks to enable quantum optics.
Using Si Photonics platform for integration.



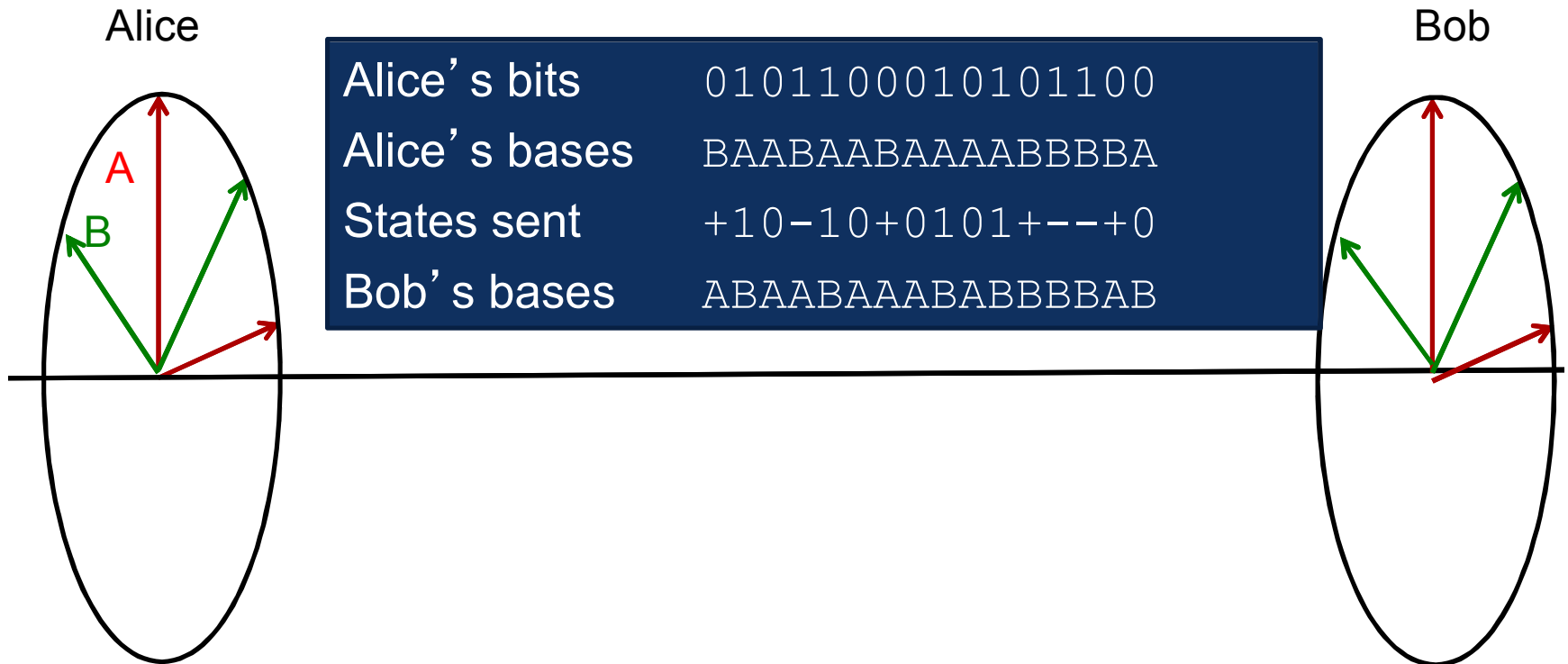
Quantum Key Distribution (QKD)

- A secure way to distribute a key that is Eve proof.
- Quantum state of photon
 - A photon is a quantum object (discrete state with wavefunction).
 - No cloning of unknown quantum state (cannot be perfectly copied).
 - Measuring quantum state perturbs state.
- Uses Physical principle (QM) to guarantee security



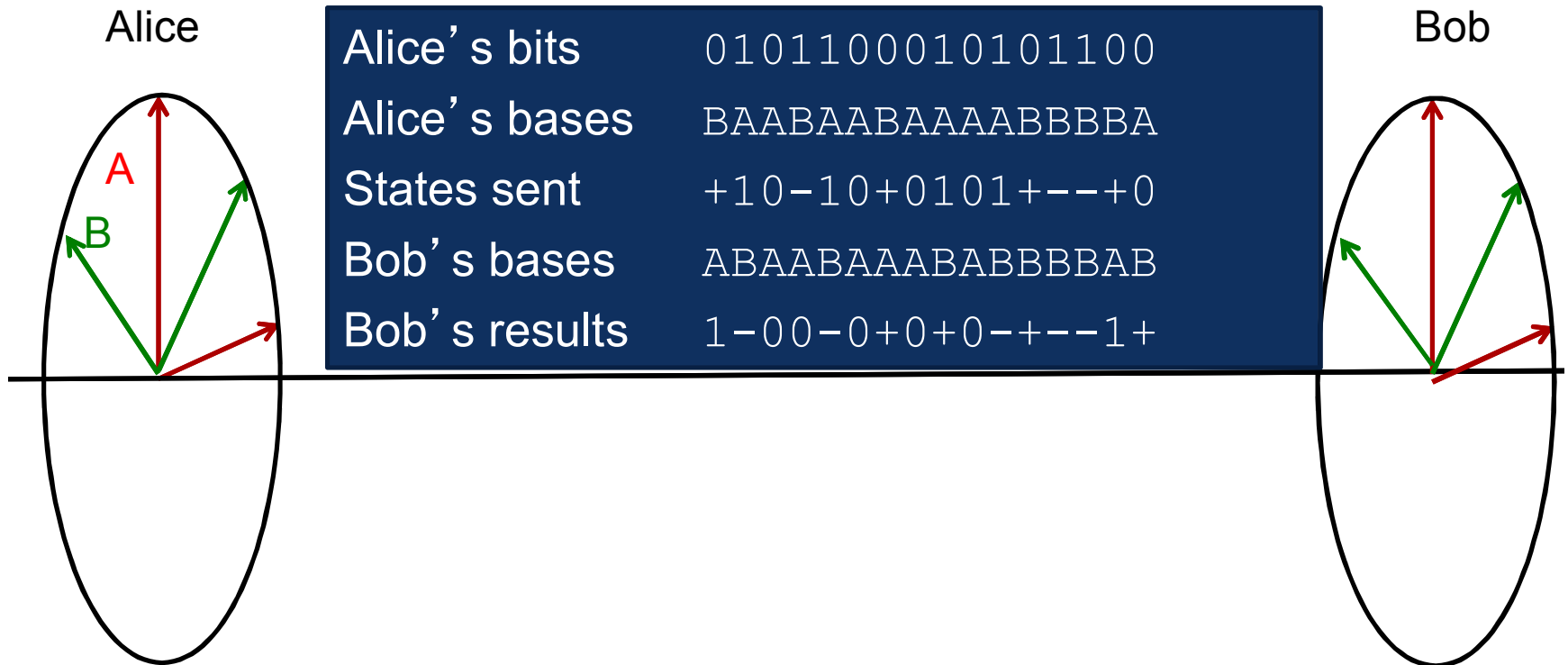
BB84 (Bennett and Brassard)

- Polarization state of photon:
- Two orthogonal bases: A (x-y) & B (rotated by 45°)
- Alice and Bob define bases and define 0 & 1 in A & B



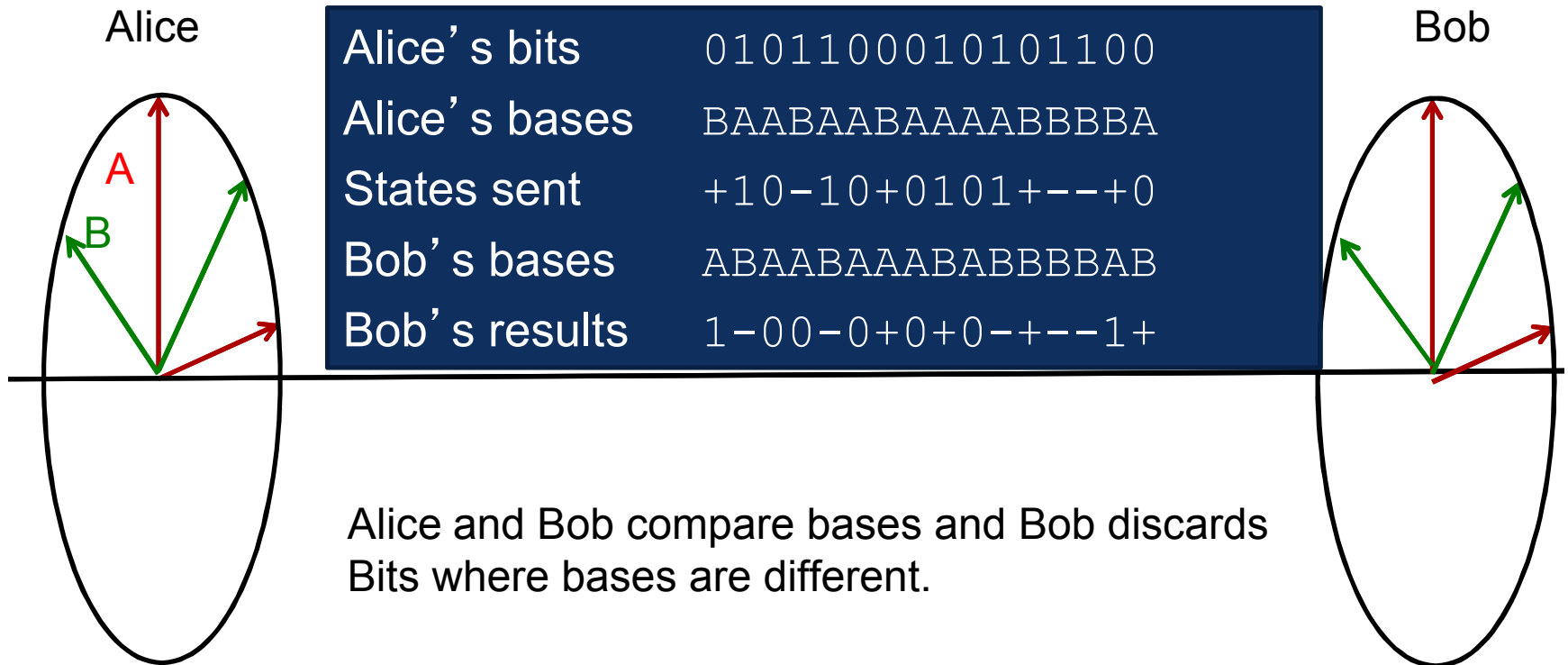
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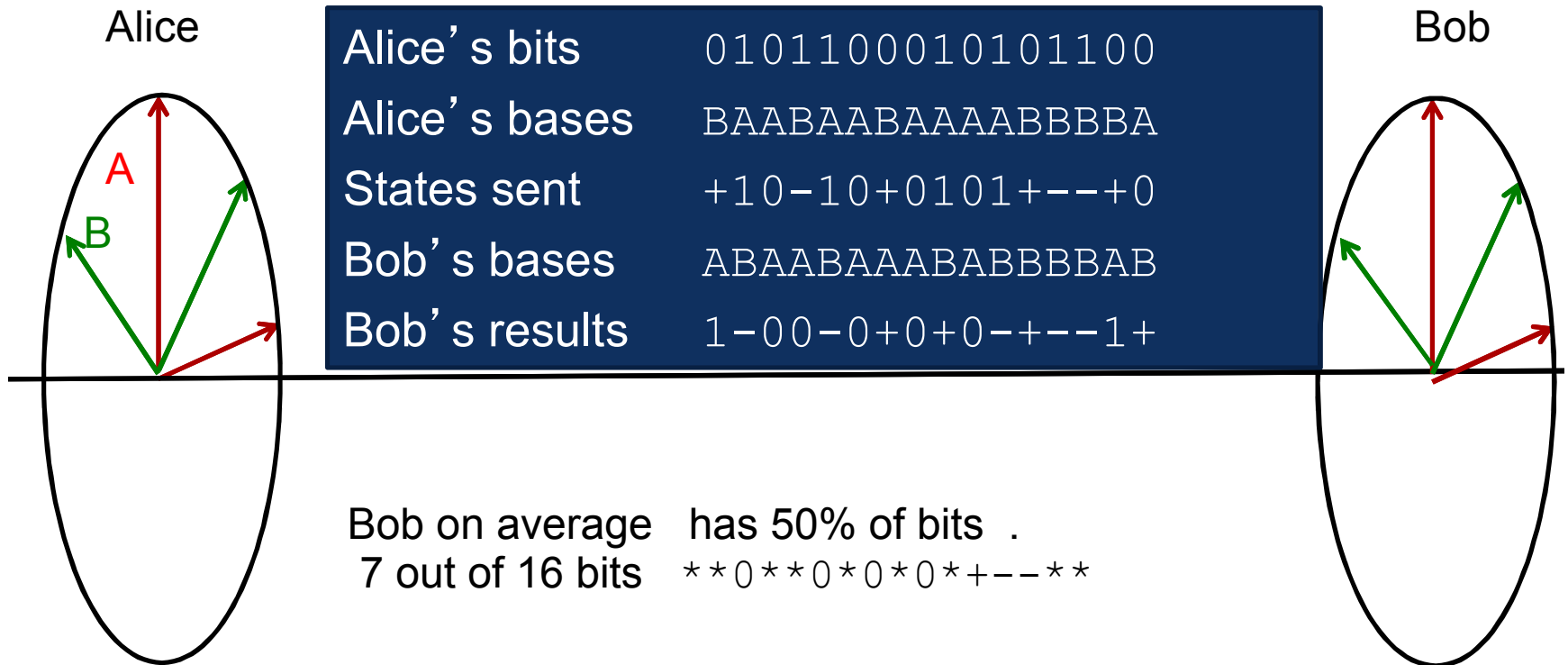
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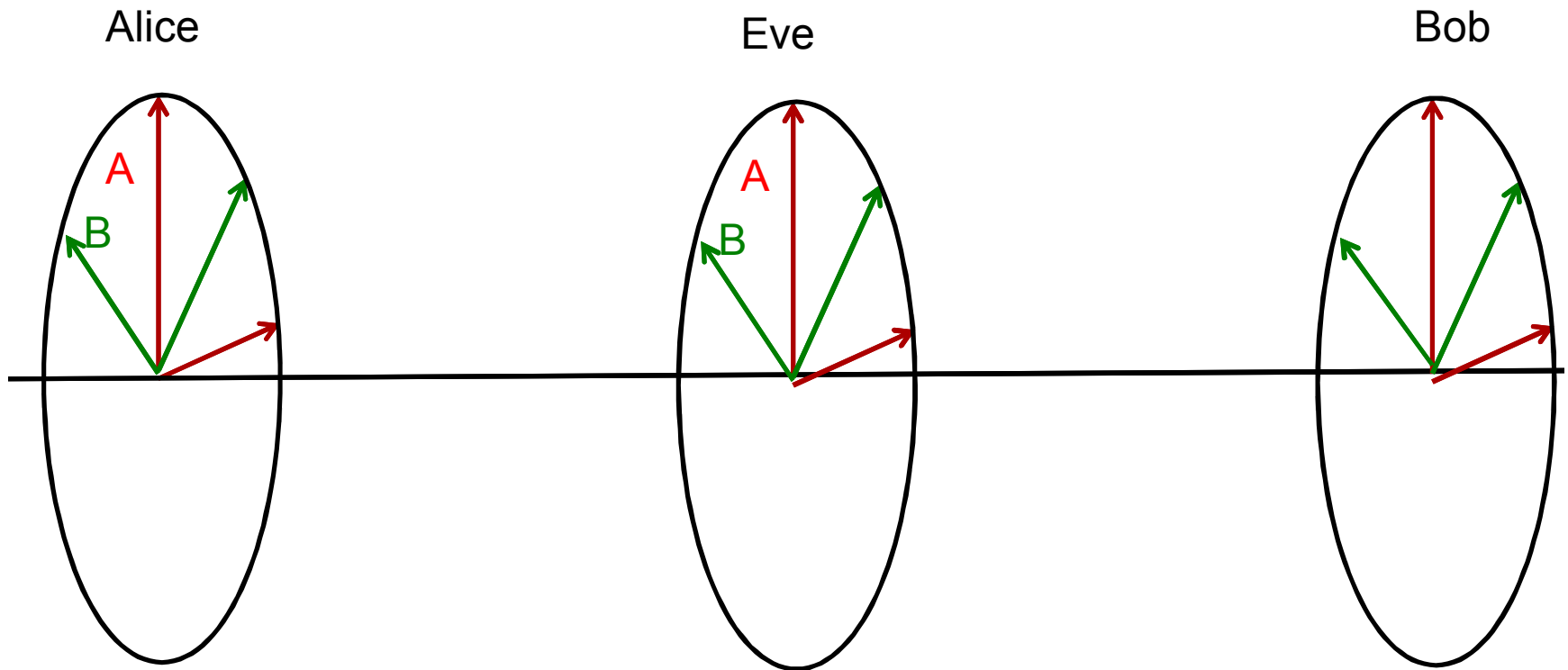
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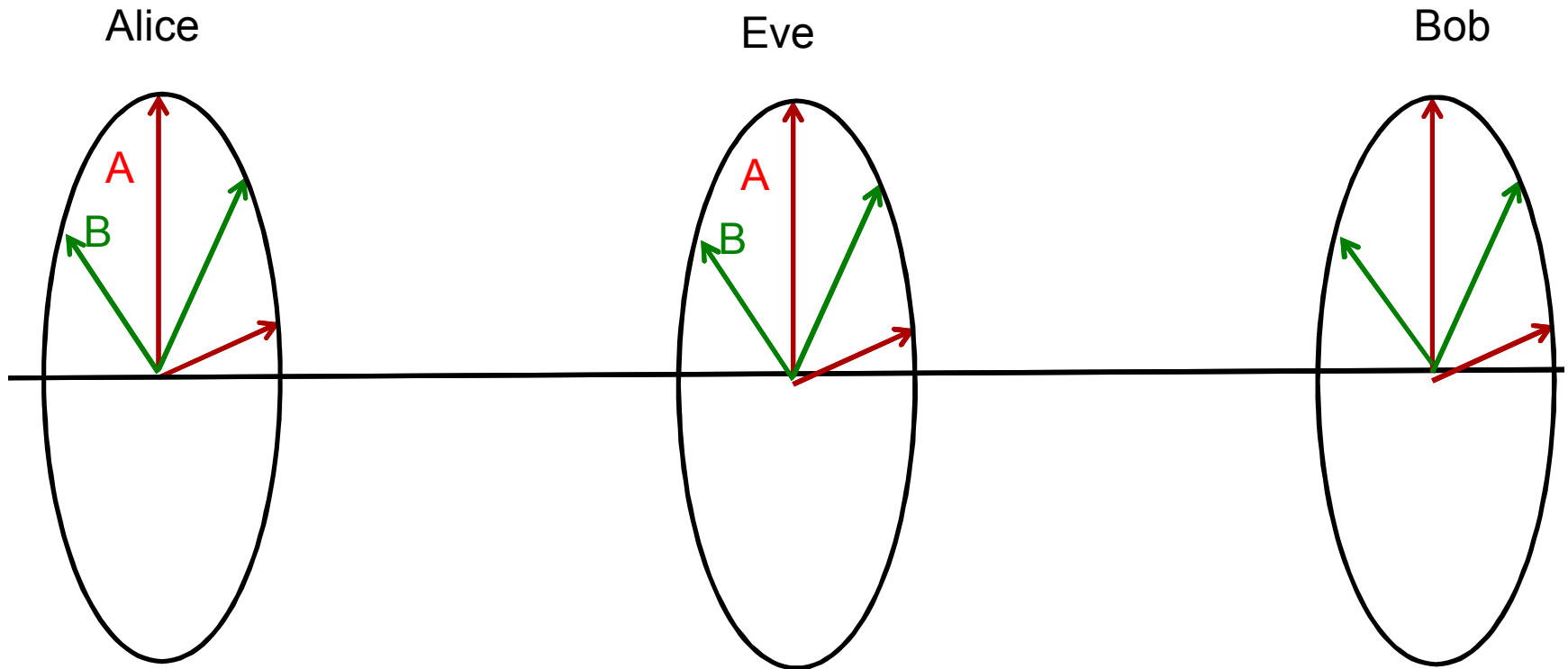
BB84 (Bennett and Brassard)

- Eve is in the middle
- Eve random selects polarization
- Based on Eve's measure and basis she sends photon.



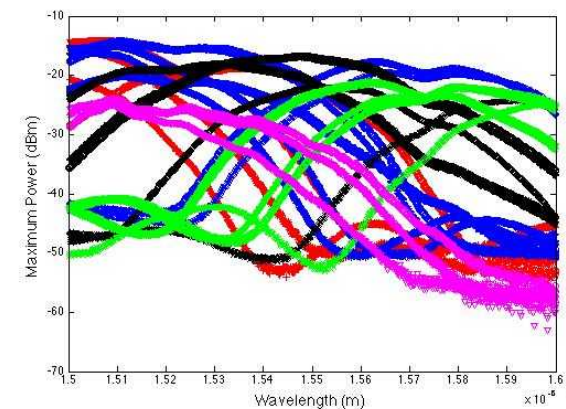
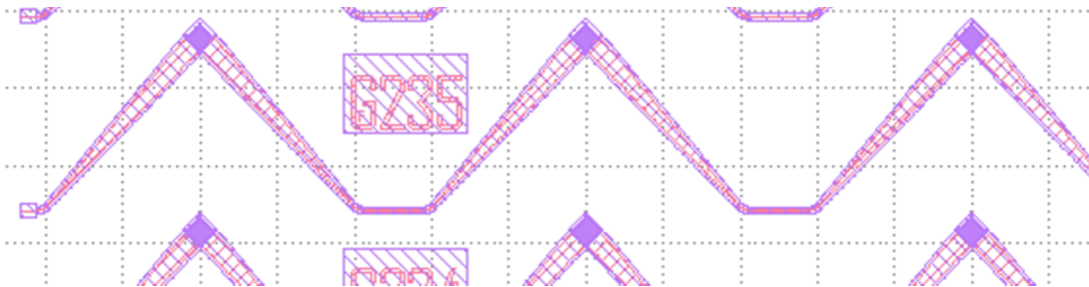
BB84 (Bennett and Brassard)

- Eve has 50% correct basis with Alice.
- Bob has 25% correct bits with Alice during reconciliation.
- No attack obtaining full information about the key can introduce less than 11% QBER.



DV-QKD Transceiver

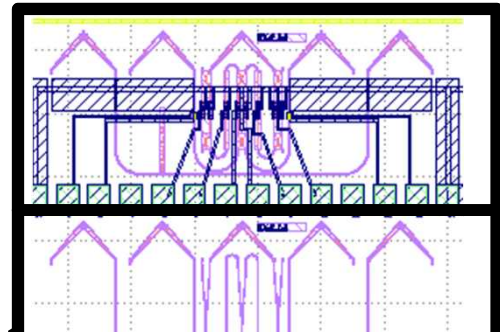
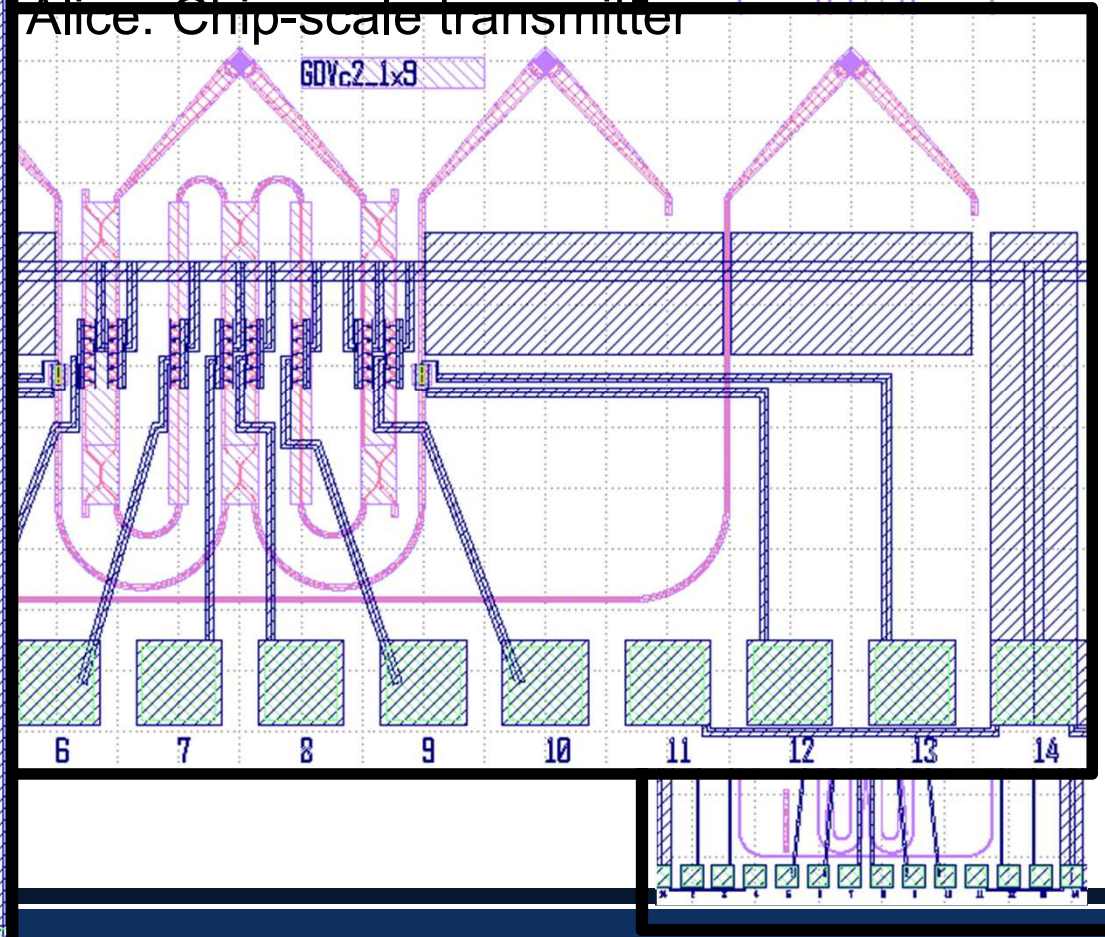
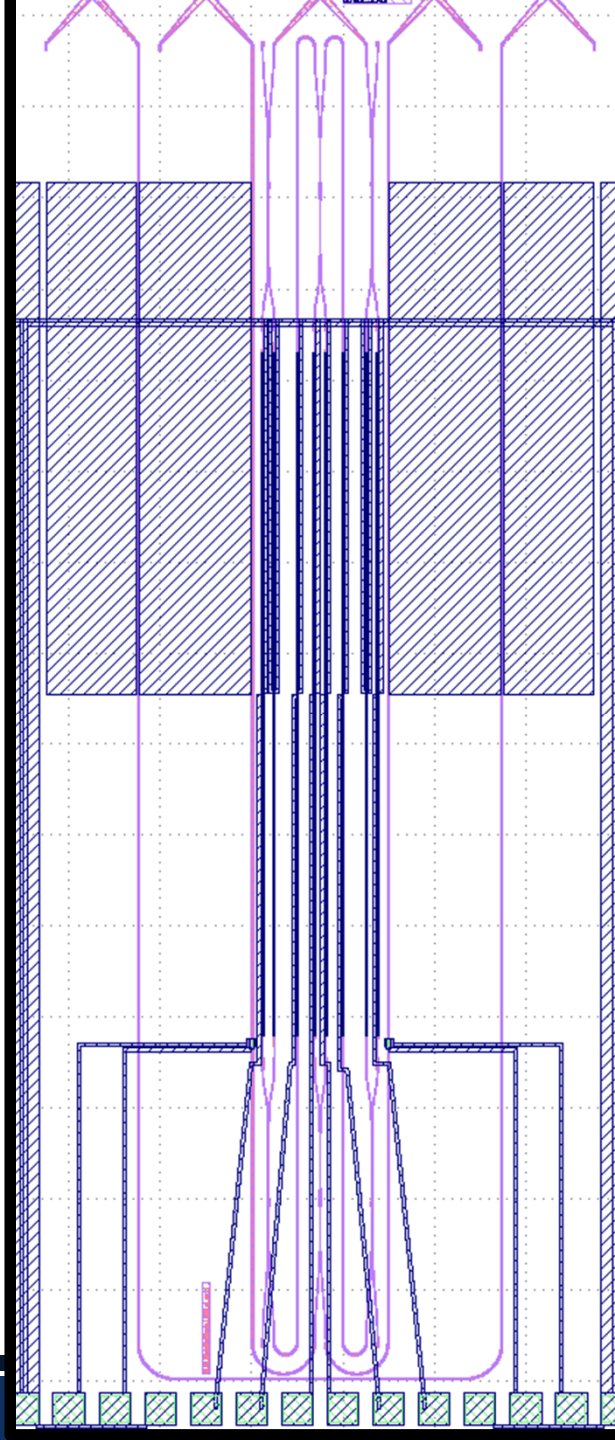
- Free-space DV QKD Tx/Rx design complete using BB84 polarization.
- New chip-scale polarization components designed, fabricated and tested.
 - Polarization gratings, rotators and splitters. 14 dB grating loss at 1520 nm.
 - 1800 grating measured.
- Issues: DV-Tx/Rx run delayed due to cost overrun. Merge with MPW. No current integrated SPAD is risk of DV-RX



/ Tx/Rx

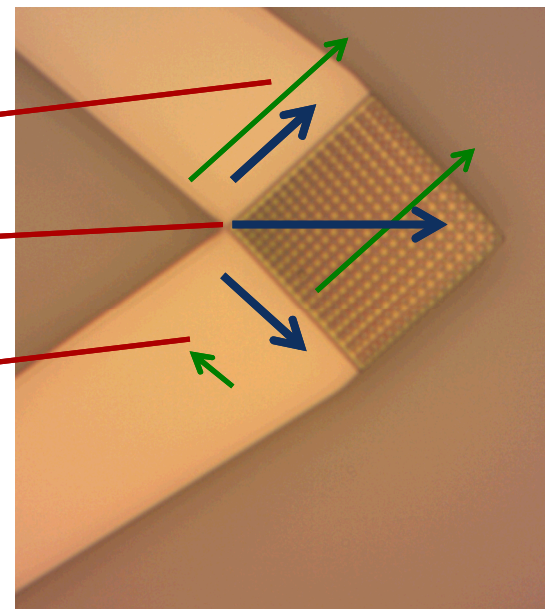
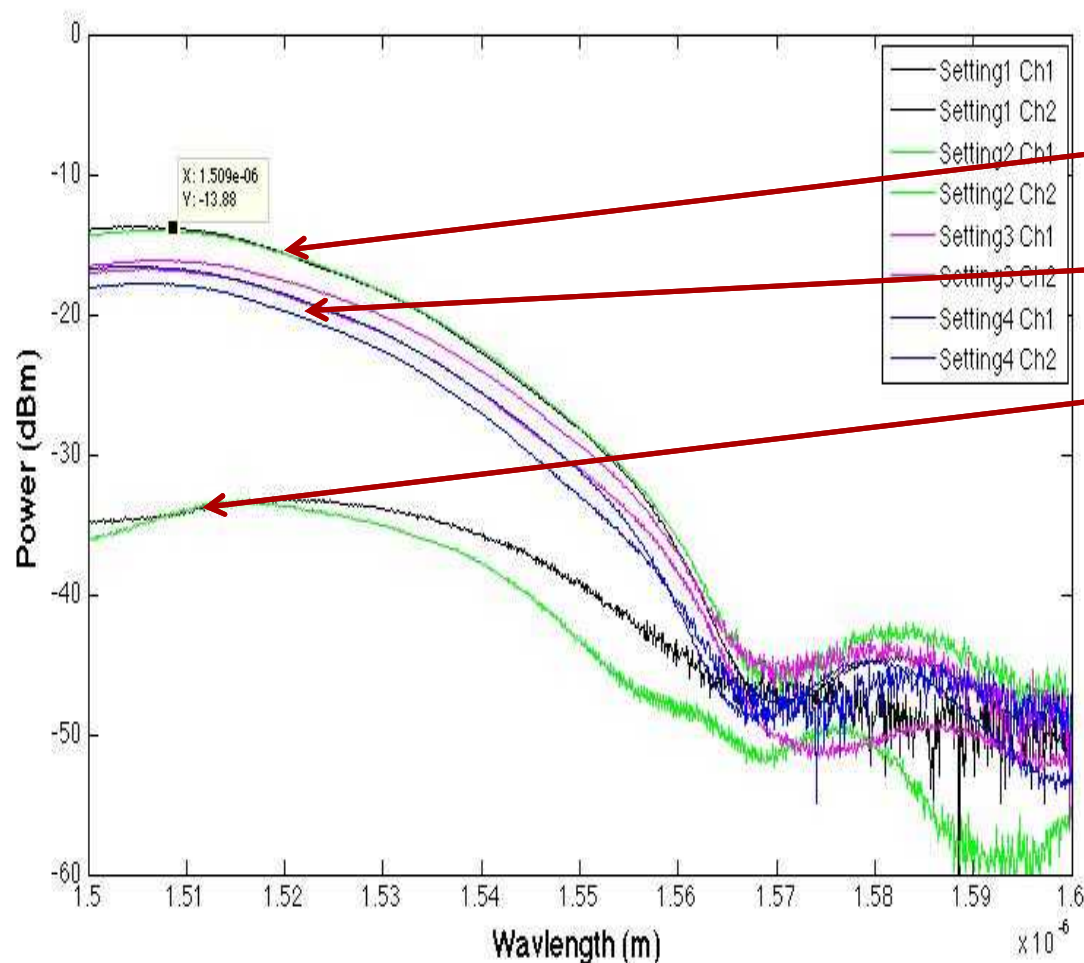
Bob: Receiver with
Integrated SPAD

Alice: Chip-scale transmitter



Waveguide polarization gratings

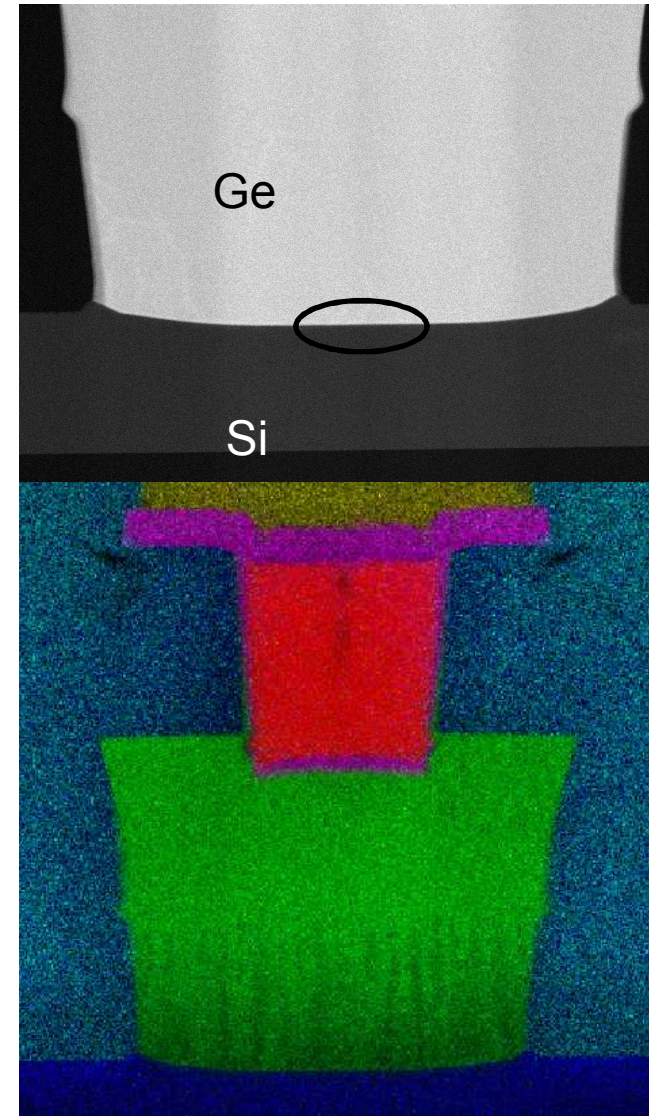
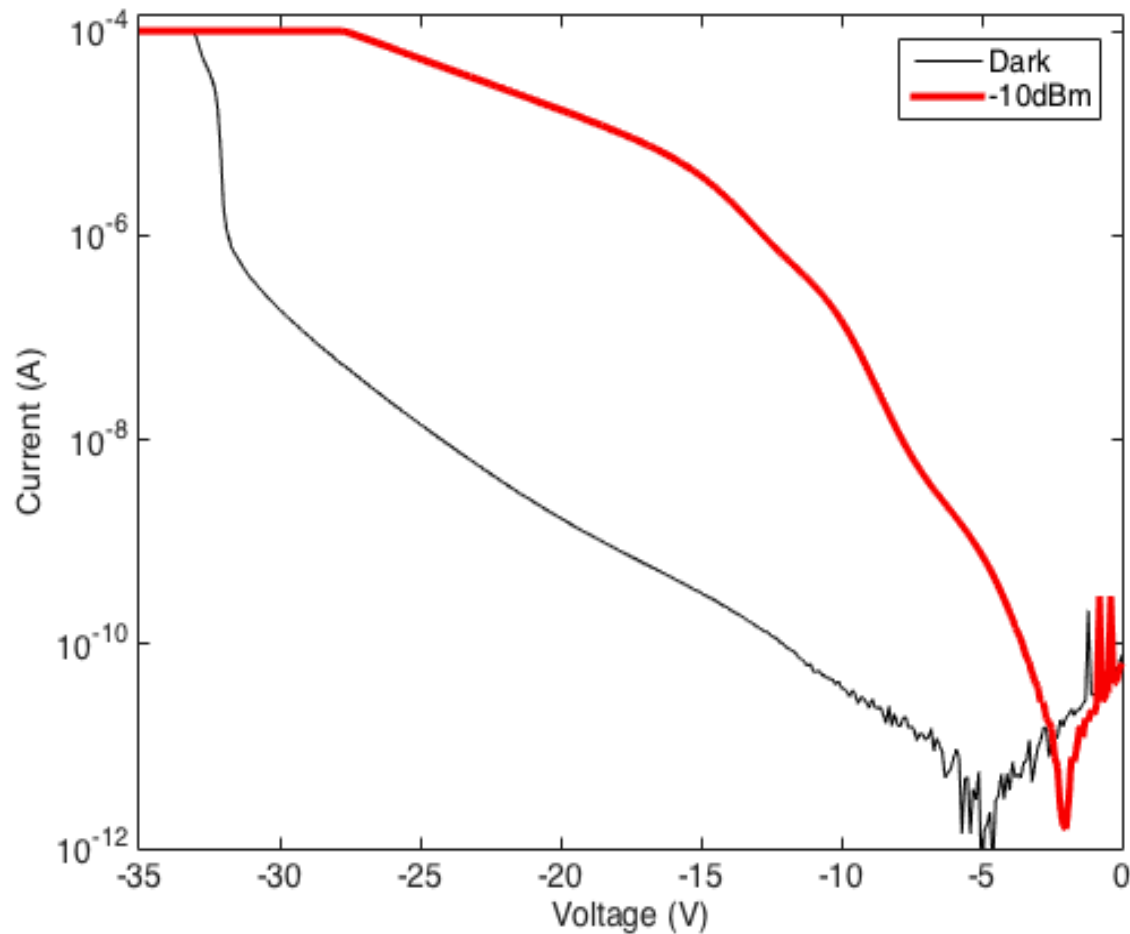
New polarization components developed for Free-space DV QKD with BB84



3dB split for blue polarization

SPAD Development

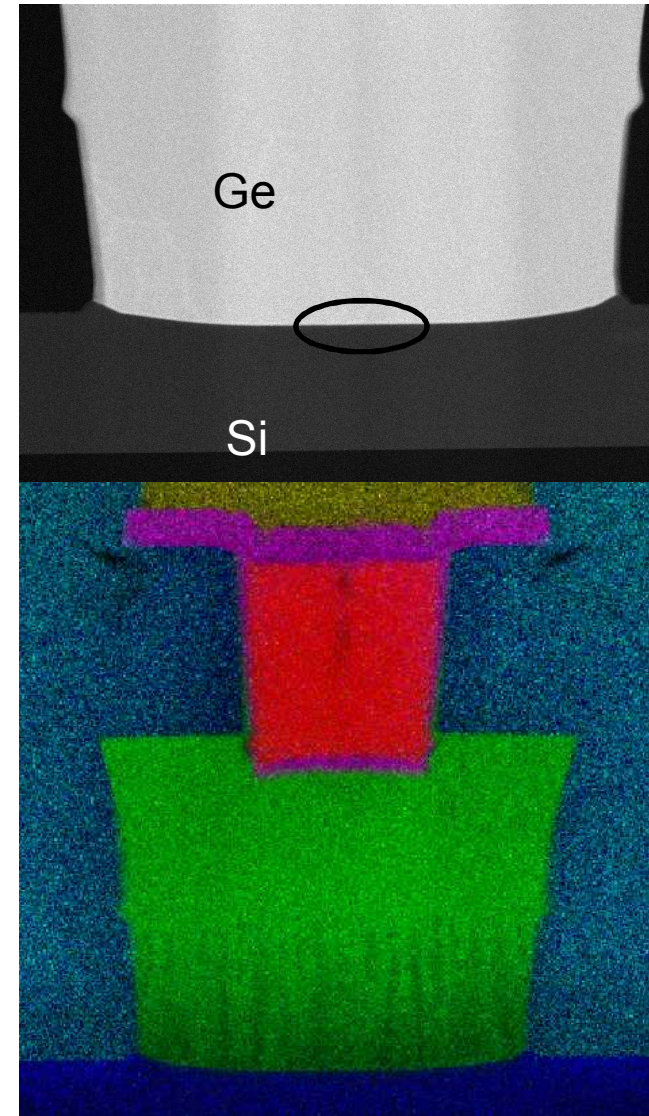
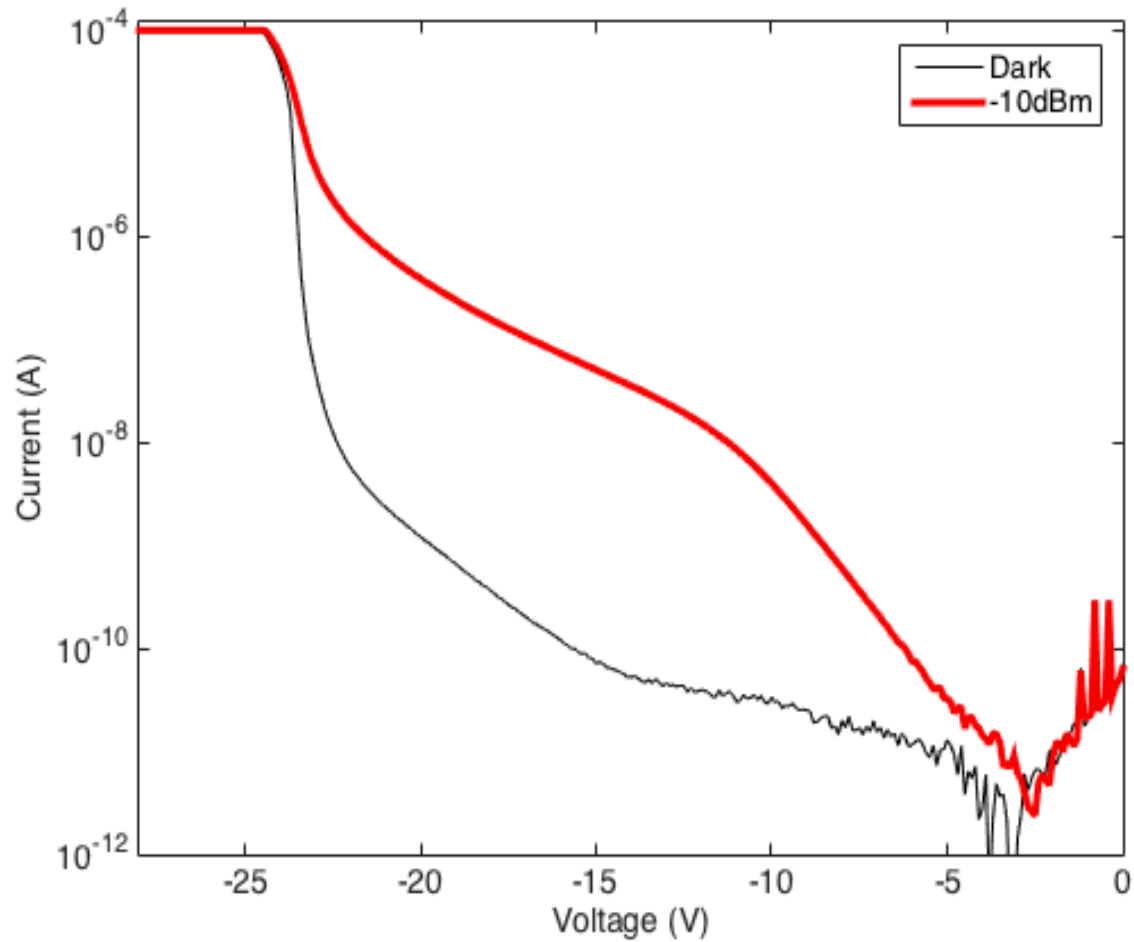
High responsivity design



-5dBm applied

SPAD Development

Low Dark Current design



Integrated SPAD Development

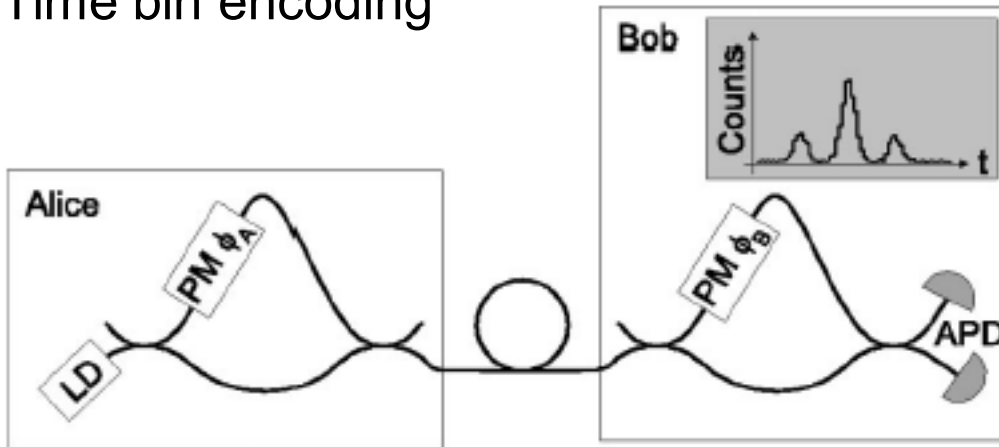
- Pad re-design (GSSG) on new SPAD devices enable high speed testing for lateral APDs.
 - High speed testing on probe station possible for lateral APDs.
 - New pulsed laser will enable jitter measurements through sync.
 - DCR measurements on new lateral APD chips underway.
- Tested 1st evanescent ntirde coupled vertical APDs.
- 2nd Ge Epi source qualification evaluation.
 - Preliminary results not promising for Ge epi.
 - Si Epi looks good.
- Issues: CMP over-polish of Ge on vertical Epi Si/Ge structures removed nearly all Ge. Need new process runs with full Ge to develop process.

Time Bin Encoding

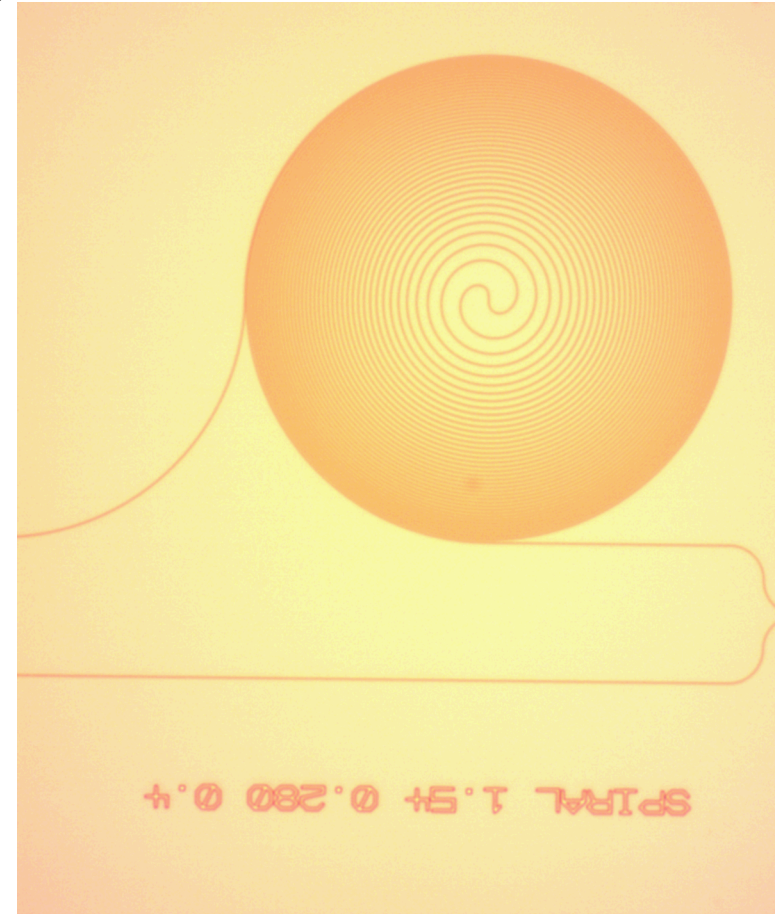
N.Gisin, et. al. "Quantum Cryptography, Rev. Mod Phys, 75 2002

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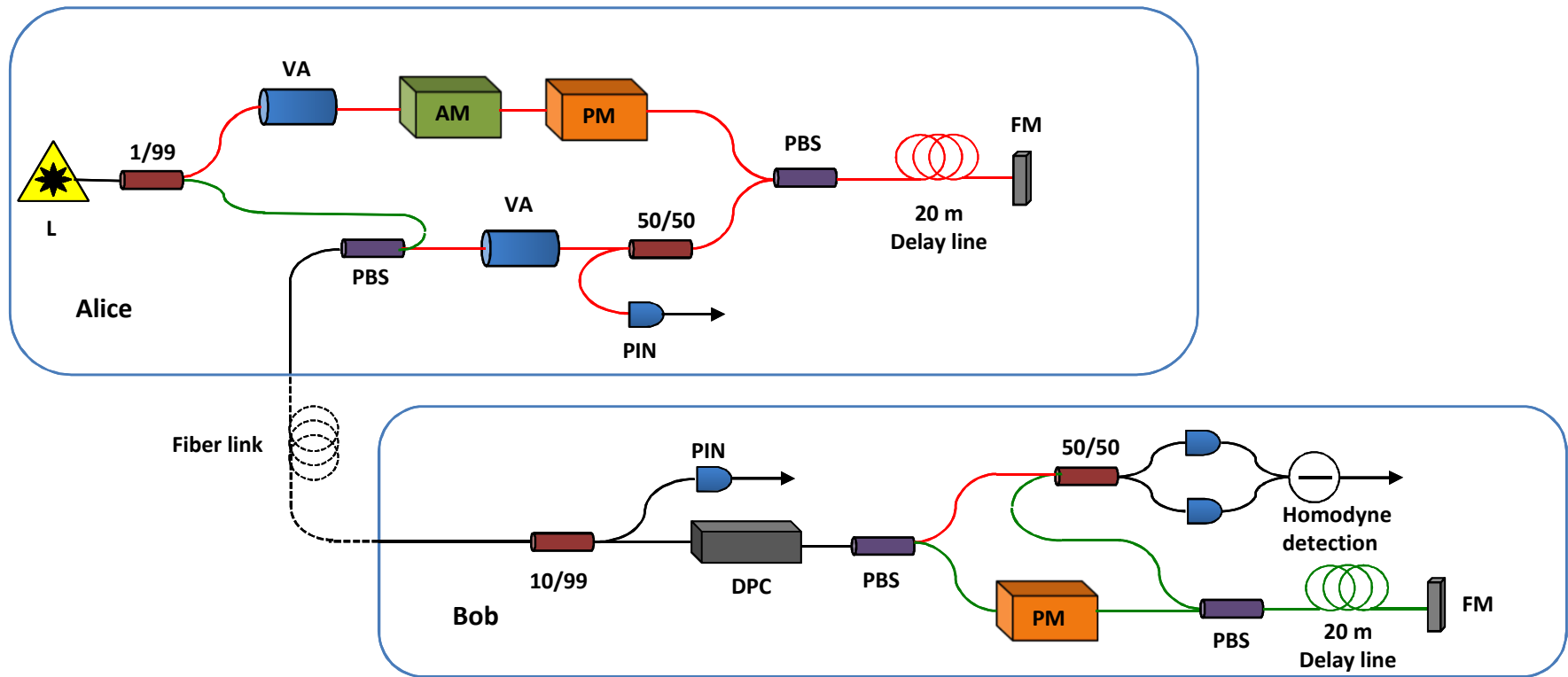
Time bin encoding



Long delay (ns) in waveguides leads to large loss
Must reduce loss for chip-scale time-bin encoding



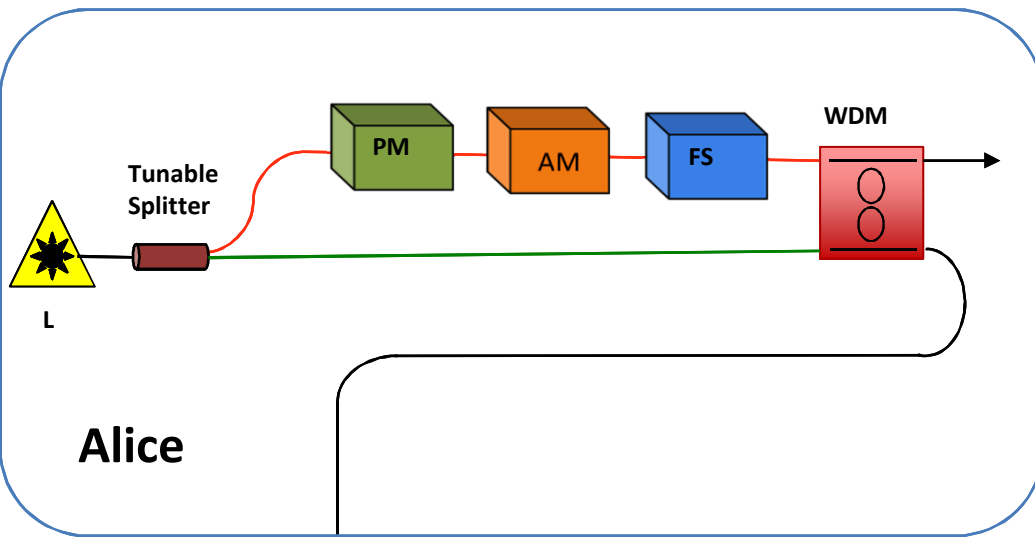
Bench-top CV-QKD link



Current State of the Art CVQKD link using coherent state source

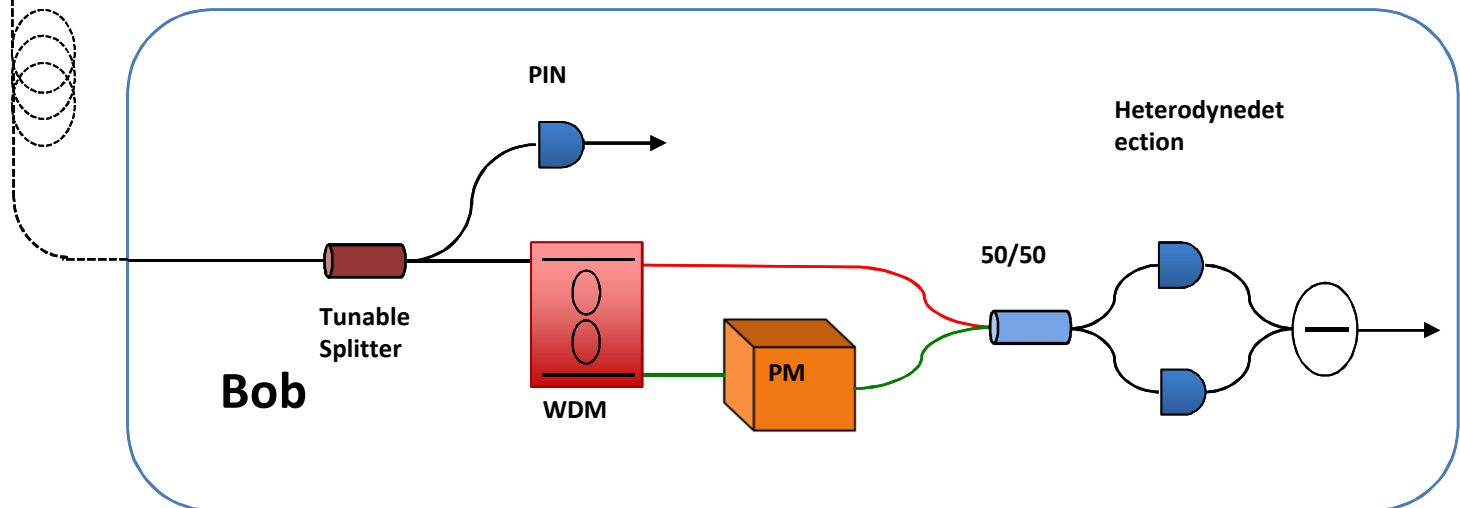
P. Jouguet, S. Kunz-Jacques, A. Leverrier, P. Grangier, and E. Diamanti. Experimental demonstration of long-distance continuous-variable quantum key distribution. *Nature Photonics*, 7(5):378–381, 2013.

On-Chip CV-QKD System



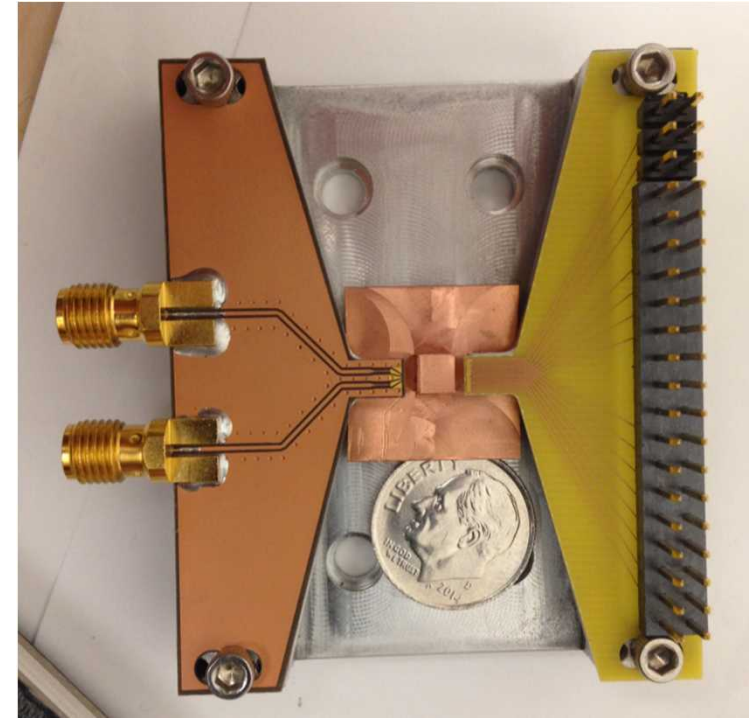
- Using frequency shifter and WDM to eliminate requirement for time delayed optical pulses
- System size is less than 4mm^2
- Implementation using demonstrated devices.

Fiber link

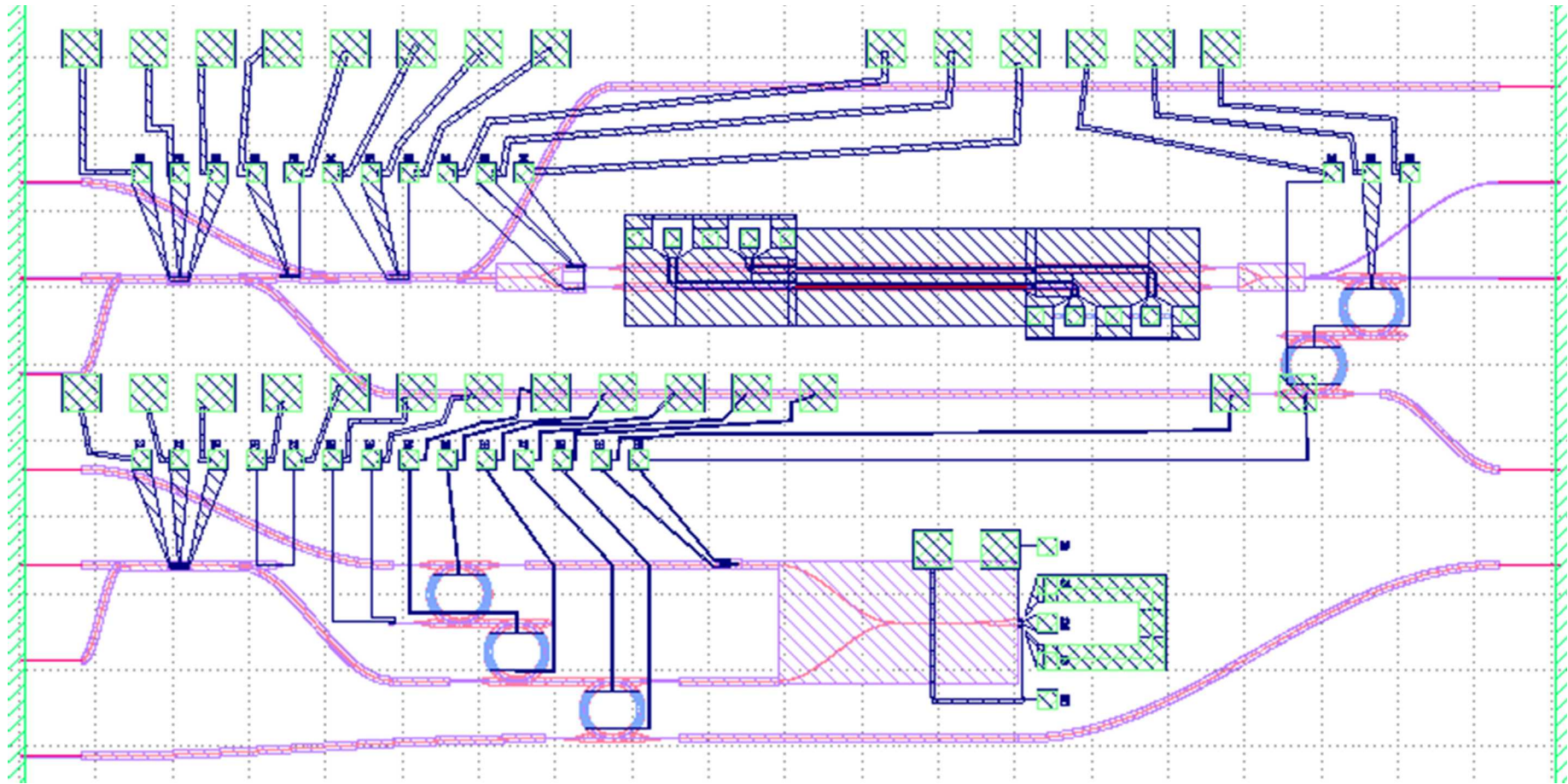


Chip-scale CV-QKD Transceiver

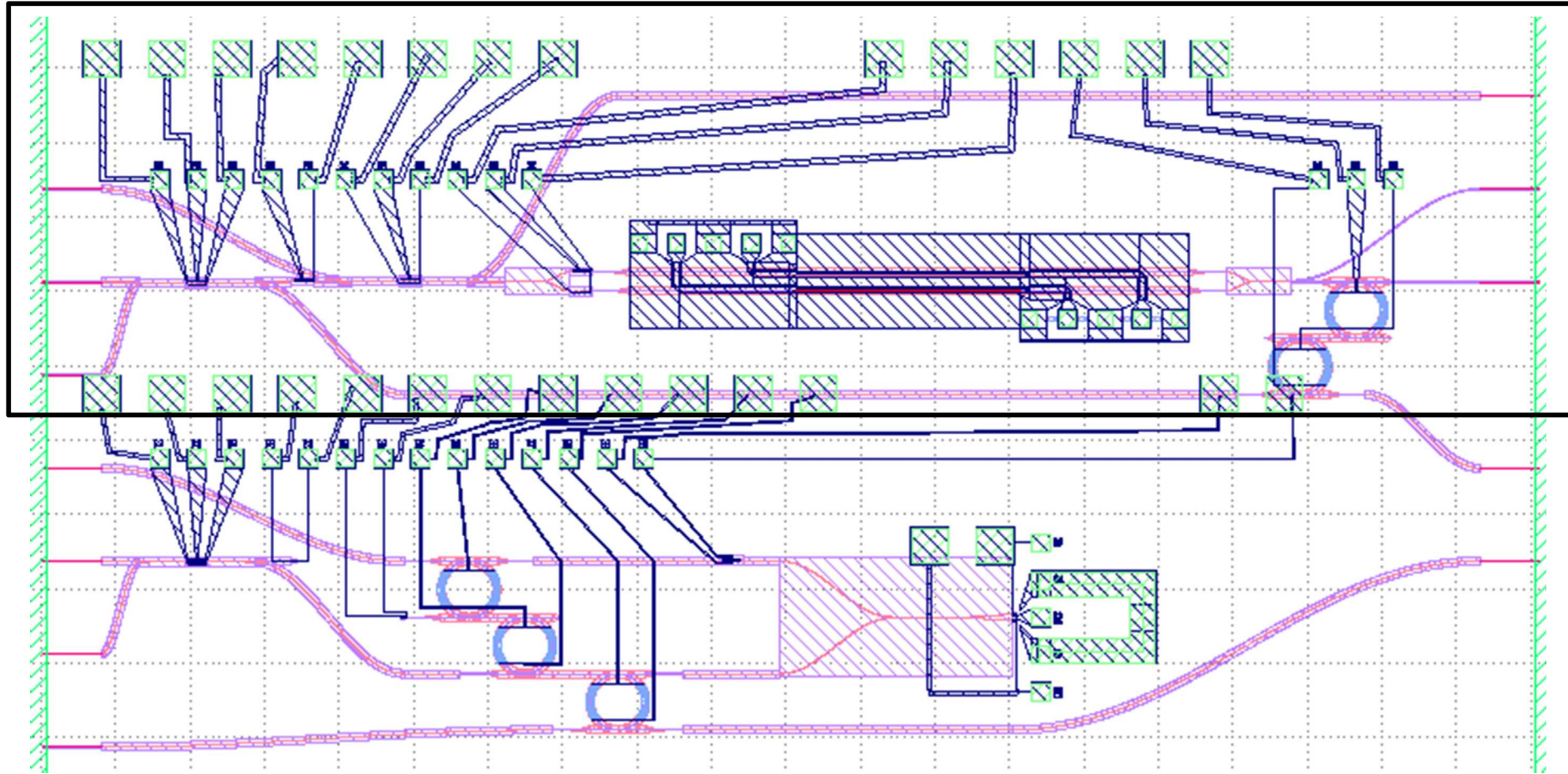
- Modified from Granger-Diamanti bench-top design due to difficulty in long delays on chip.
- Uses well-characterized existing devices within Sandia's Si Photonics platform.
- Can use coherent states or squeezed states.
- Need to develop simple package for protocol testing.



CV-TX/RX Layout



Alice CV-Tx

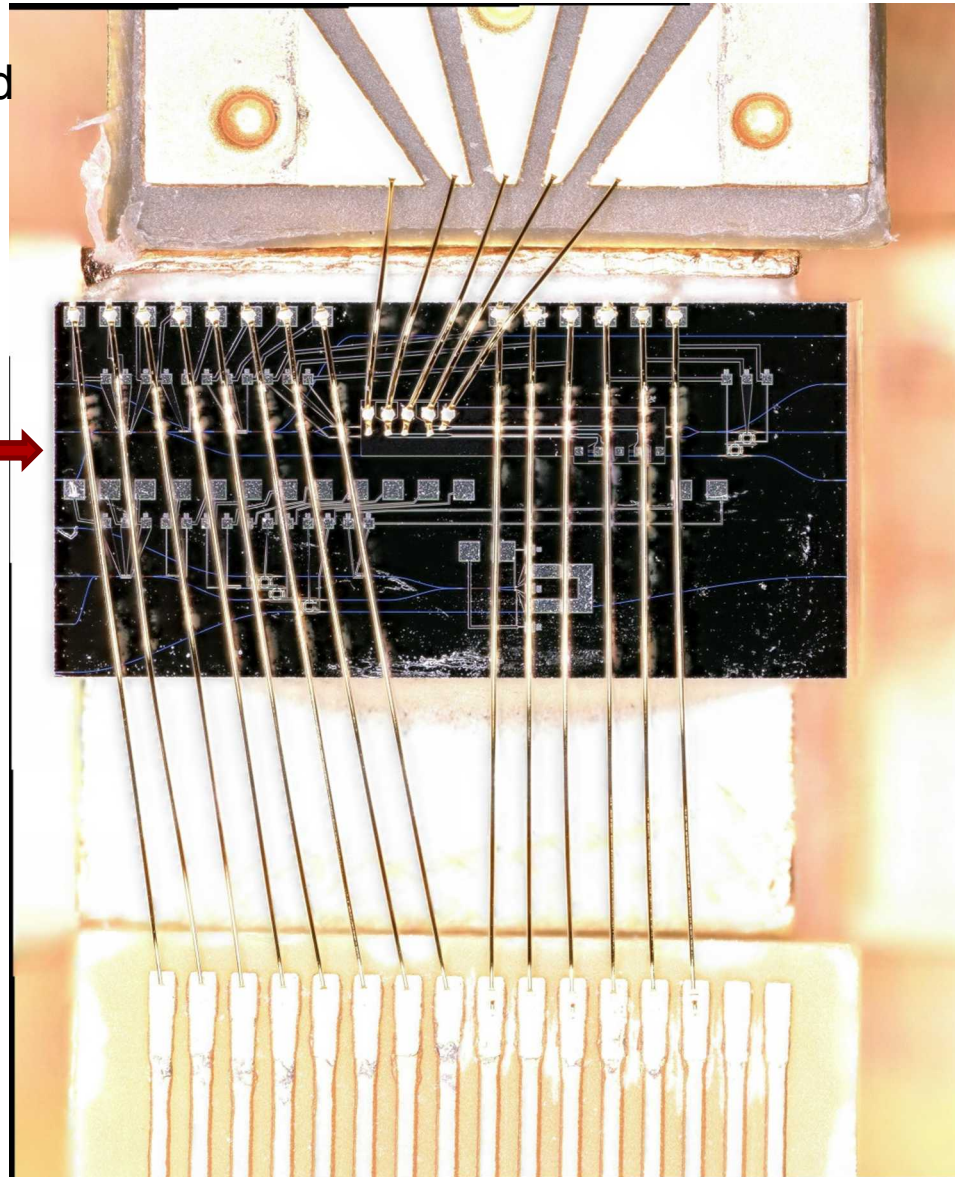


Wire-Bonded CV-TX

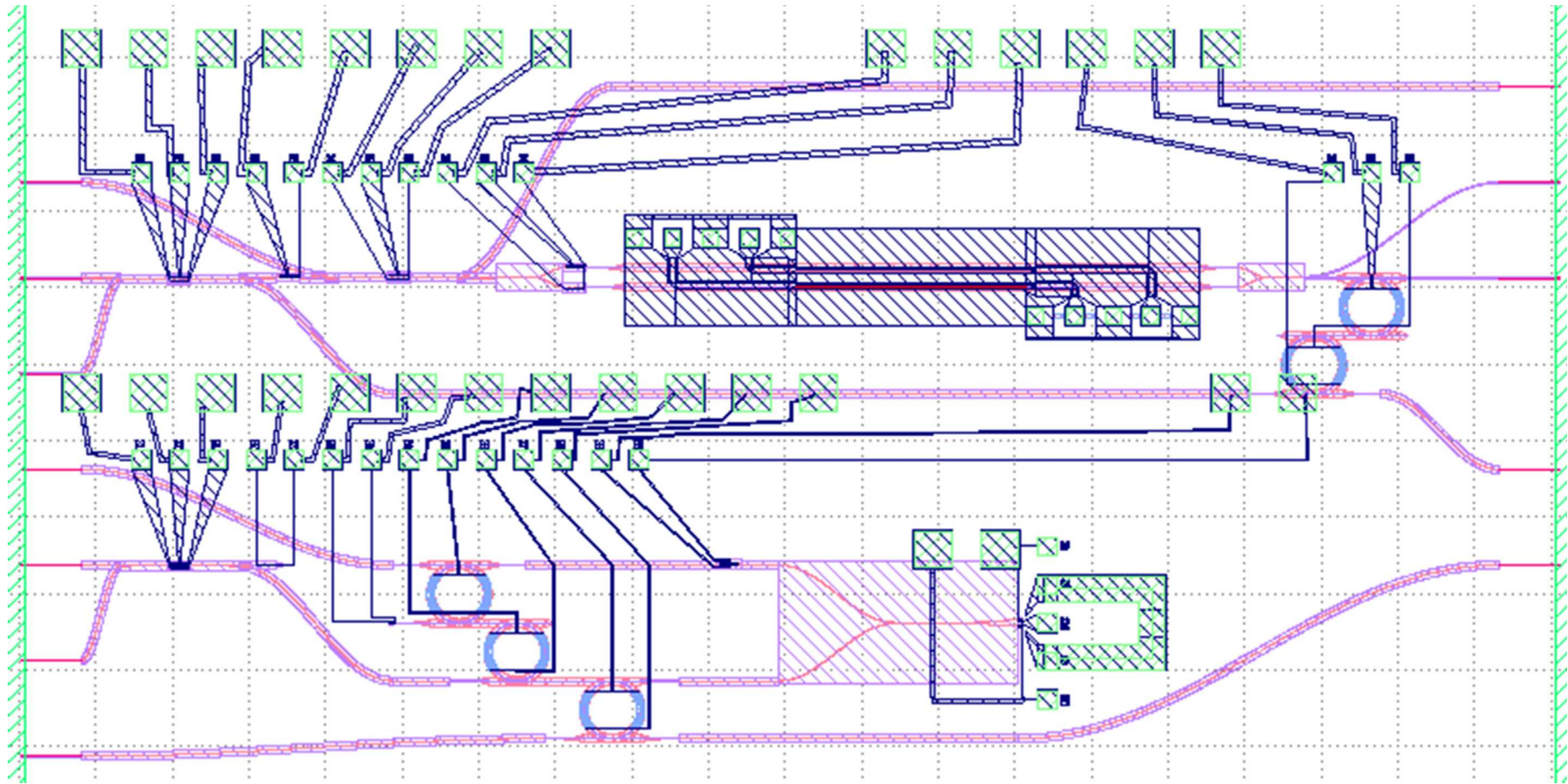
High speed board
> 25 GHz

Fiber input 

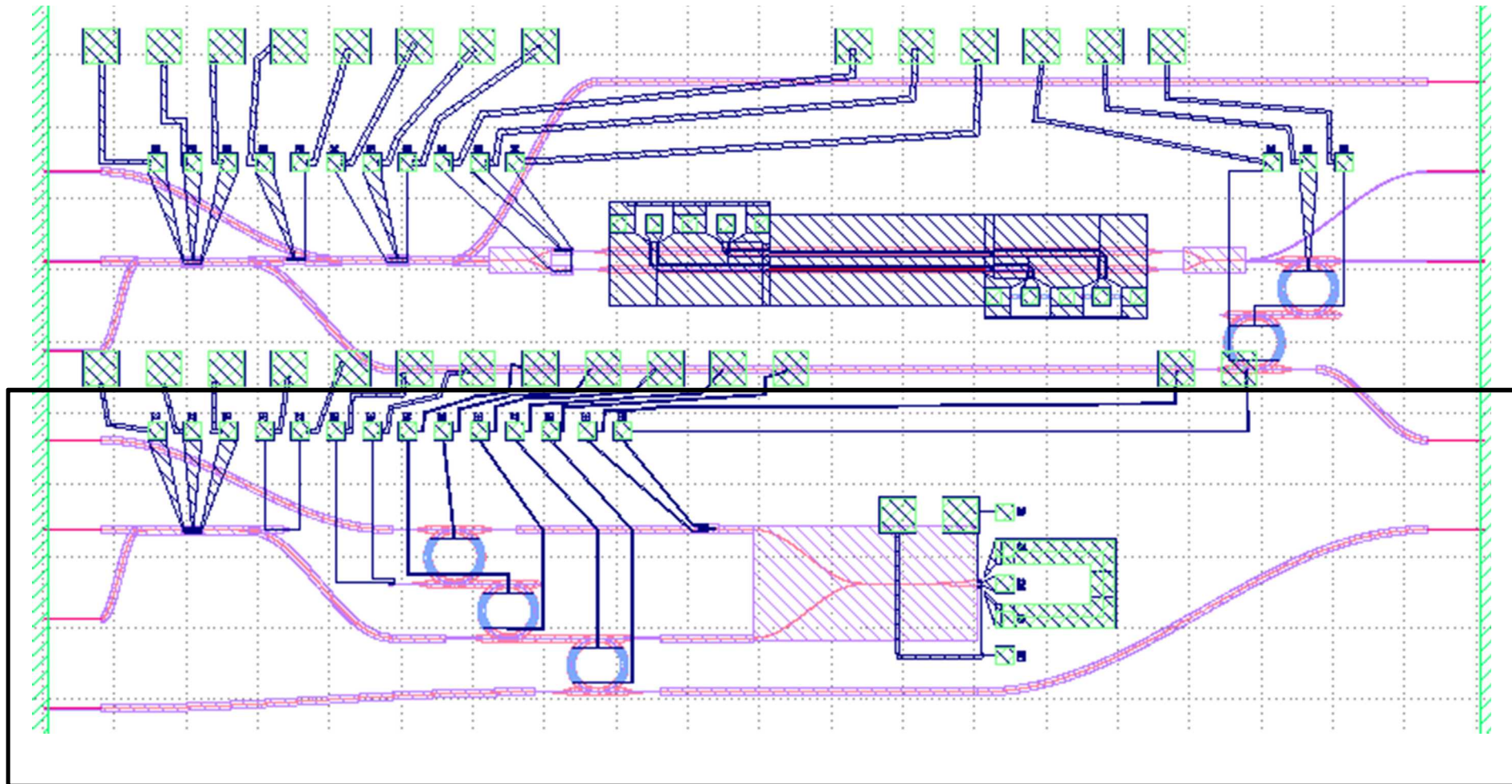
DC /Low speed
< 1MHz



CV-TX/RX Layout



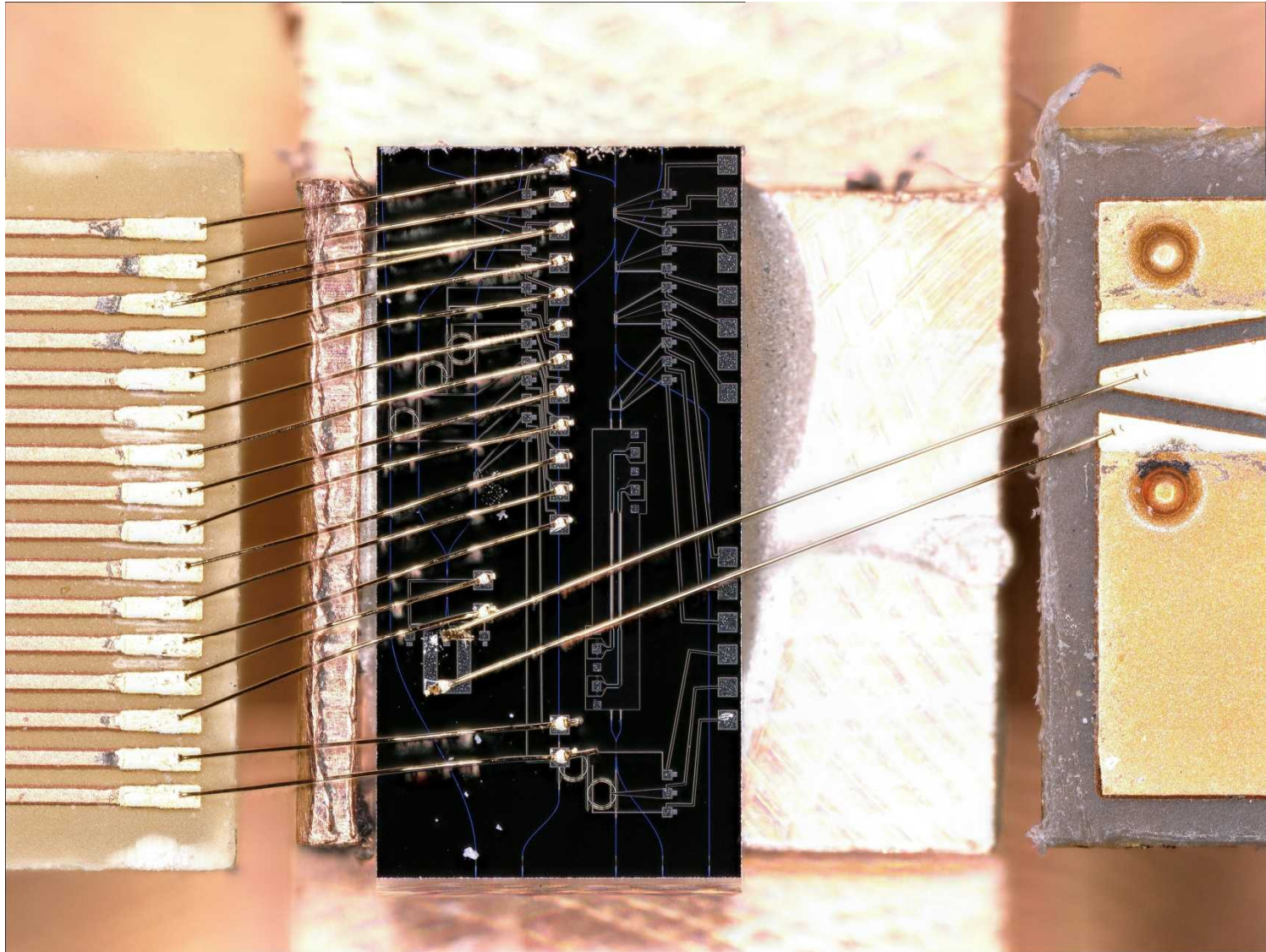
Bob CV-Rx



7/8/2015

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CV-Receiver



Summary

- Reviewed Sandia's Si Photonics platform.
- Highlighted Quantum Communications research direction.
- Chip-scale Quantum Key Distribution as a demonstration vehicle.
 - Two different chip-scale protocols
 - Free-space BB84 using new chip-scale polarization control devices.
 - Requires integrated Single Photon detection capability.
 - Fiber Continuous variable QKD
 - New Protocol development for on-chip CV.
- Designed & Testing Transceivers!